

International Conference on Crystal Growth and Epitaxy 30 July - 4 August 2023, Naples (Italy)

















Conference Chairs

Antonio Vecchione, SPIN-CNR, Salerno, Italy Andrea Zappettini, IMEM-CNR, Parma, Italy

Conference Program Chairs

Geetha Balakrishnan, University of Warwick, United Kingdom Giuseppe Falini, University of Bologna, Italy

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Annalisa Guerri, University of Florence, Florence, Italy

Mariateresa Lettieri, SPIN-CNR, Salerno, Italy

Antonella Secondulfo, IMEM-CNR, Parma, Italy

Organising Secretariat



PROGRAM AT A GLANCE

TIME	Mon, 31 Jul	Tue, 1 Aug	Wed, 2 Aug	Thu, 3 Aug	Fri, 4 Aug
08:45-09:00	Opening				
09:00-09:45	Frank Prize	Plenary Lecture	Plenary Lecture	Plenary Lecture	Plenary Lecture
09:45-11:00	Parallel sessions	Parallel sessions	Parallel sessions	Parallel sessions	Parallel sessions
11:00-11:30	Coffee break	Coffee break	Coffee break	Coffee break	Coffee break
11:30-12:45	Parallel sessions	Parallel sessions	Parallel sessions	Parallel sessions	Parallel sessions
12:45-14:00	Lunch	Lunch	Lunch	Lunch	Closing
13:50-14:00		Industrial talk		Industrial talk	
14:00-14-45	Frank Prize	Laudise Prize	su	Schieber Prize	
14:45-16:00	Parallel sessions	Parallel sessions	oisruc	IOCG General Assembly	
16:00-16:30	Coffee break	Coffee break	9X∃	Coffee break	
16:30-18:30	Poster session-01	Poster session-02		Poster session-03	

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SUN, 30 JUL 17:30 - 20:00 REGISTRATION 18:30 - 21:00 WELCOME RECEPTION Santa Maria la Nova At 17:30 and 18:00 guided tours of the Convent and Church will be offered. Limited to 180 participants, on a first come first served basis 18:30 Welcome address 19:00 Cocktail

MON, 31 JUL 08:45 - 09:00 OPENING PRANK PRIZE Aula Magna Chair/s: Koichi Kakimoto Molecular mechanisms to control crystal nucleation Peter Vekilov, University of Houston

09:45 - 11:00	FUNDAMENTALS OF NUCLEATION AND CRYSTAL GROWTH-01 Aula Magna Chair/s: Linda Pastero
09:45	Invited talk-01 Controls of Interfacial Structure on Nanorod Self-Assembly at Liquid-Crystal Interfaces Jim De Yoreo, Pacific Northwest National Laboratory University of Washington
10:15	Oral presentation-02 Promotion of calcite dissolution in succinic acid and L-malic acid aqueous solution. Koudai Imura, Ritsumeikan University
10:30	Oral presentation-03 Do metastable polymorphs always grow faster? Challenges of measuring and comparing crystal growth rates of tolfenamic acid polymorphs Pietro Sacchi, Cambridge Crystallographic Data Centre
10:45	Oral presentation-04 Regrowth Behaviour in Pharmaceutical Crystals - A Case Study on Paracetamol Isha Bade, Chemical Engineering, Imperial College London
09:45 - 11:00	GROWTH AT THE NANOSCALE: NANOCRYSTALS, NANOWIRES, NANOMATERIALS-01 SG-T-1 Chair/s: Stefano Sanguinetti
09:45 - 11:00 09:45	NANOMATERIALS-01 SG-T-1
	NANOMATERIALS-01 SG-T-1 Chair/s: Stefano Sanguinetti Invited talk-01 Selectivity Control of InAs Shells on Crystal Phase Engineered GaAs Nanowires
09:45	SG-T-1 Chair/s: Stefano Sanguinetti Invited talk-01 Selectivity Control of InAs Shells on Crystal Phase Engineered GaAs Nanowires Victor Gomez, Universitat Politecnica de Valencia Oral presentation-02 Quantum Dot Nanowires For Telecom Single Photon Emission at Elevated Temperatures

09:45 - 11:00	BULK CRYSTAL GROWTH-01
	SG-T-2 Chair/s: Rosalba Fittipaldi
09:45	Invited talk-01 Self-selecting vapor growth of transition metal halide single crystals Jiaqiang Yan, Oak Ridge National Laboratory
10:15	Oral presentation-02 Flux growth and characterization of bulk InVO ₄ crystals Olesia Voloshyna, IFW Dresden, Germany
10:30	Oral presentation-03 Growth and properties of Ti ³⁺ : Al ₂ O ₃ single-crystal Jan Havlíček, Crytur, spol. s r.o.
10:45	Oral presentation-04 Growth of NaBaCr₂(PO₄)₃ crystals by high temperature solution method Alexandra Peña Revellez, Université Grenoble Alpes, CNRS, Grenoble INP, Institut Néel, 38000 Grenoble, France
09:45 - 11:00	OPTICAL CRYSTALS-01
	SG-I-1 Chair/s: Carlo Altucci
09:45	Invited talk-01 Optically active plasmonic glass composites fabricated by crystal growth techniques Piotr Piotrowski, Centre of Excellence ENSEMBLE3 University of Warsaw
10:15	Oral presentation-02 Crystal Growth of KBBF and Prism-free Doubler for deep-UV Generation Xiaoyang Wang, Technical Institute of Physics and Chemistry, Chinese Academy of Sciences, et al.
10:30	Oral presentation-03 Heteroepitaxy of patterned ternary nonlinear optical materials for frequency conversion of laser sources in the mid and longwave IR Vladimir Tassev, Air Force Research Laboratory
10:45	Oral presentation-04 Crystal structure variation of rare earth-doped LiNbO ₃ during milling Gabriella Dravecz, Wigner RC

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09:45 - 11:00	NEW METHODS AND TECHNIQUES FOR CRYSTAL GROWTH-01 SG-I-2
	Chair/s: Christo Guguschev, Jan Pejchal
09:45	Invited talk-01 Oxide Crystal growth from Cold Crucible; Ce doped Gd ₃ (Al,Ga) ₅ O ₁₂ and β-Ga ₂ O ₃ as examples. Akira Yoshikawa, Tohoku University C&A corporation
10:15	Oral presentation-02 SiGe epitaxial growth via pulsed laser annealing of Al-Ge pastes on Si Takeshi Sato, Nagoya University, et al.
10:30	Oral presentation-03 Ultrahigh-quality SiC single crystal grown by multi-step Peng Gu, Meishan Boya Advanced Materials Co., Ltd. School of Earth and Space Sciences, Peking University
10:45	Oral presentation-04 Seed-free solid-state growth, structure and electrical properties of bulk KNN-based crystals Minhong Jiang, Guilin University of Electronic Technology
09:45 - 11:00	FUNCTIONAL CRYSTALS-01
	SG-II-1 Chair/s: Alberta Bonnani, Adele Sassella
09:45	Invited talk-01 Study on Pulsed Electron Deposition as an effective method for thin films growth of room temperature multiferroic BaFe ₂ O ₄ Michele Casappa, University of Parma Department of Chemistry, Life Sciences and Environmental Sustainability
10:15	Oral presentation-02 Study of the mechanism for electrically erasable writing of ZnS films by conductive atomic force microscopy Lingyan Xu, Northwestern Polytechnical University
10:30	Oral presentation-03 Growth and characterization of Dy _{1-x} Y _x MnO ₃ single crystals by optical floating zone technique: A combined X-ray diffraction and DC magnetization study Anandha babu Govindan, Sri Sivasubramaniya Nadar College of Engineering Indian Institute of Technology (Banaras Hindu University) Indira Gandhi Centre for Atomic Research
10:45	Oral presentation-04 Crystallization of thick polycrystalline layers of hybrid perovskites on pixel matrices: specific opportunities and challenges for direct X-ray detection. Julien ZACCARO, Institut Néel - CNRS

09:45 - 11:00	ABVANCES IN ORSERVATION AND SHARASTERITATION METHODS OF
09.43 - 11.00	ADVANCES IN OBSERVATION AND CHARACTERIZATION METHODS-01 SG-II-2
	Chair/s: Cinzia Giannini, Luke Rhodes
09:45	Invited talk-01 X-ray Interference in Colloidal Nanocrystal Superlattices: a Parallel with Multilayer Epitaxial Thin Films Stefano Toso, Istituto Italiano di Tecnologia, Via Morego 30, 16163, Genova, IT Università Cattolica del Sacro Cuore, 25121 Brescia, Italy
10:15	Oral presentation-02 Characterization of Defects in SiC Substrates for Power Device Applications by Birefringence Imaging Shunta Harada, Nagoya University, et al.
10:30	Oral presentation-03 A first step towards the identification of Herbertsmithite Zn _x Cu _{4-x} (OH) ₆ Cl ₂ single crystal growth and point defects formation mechanisms Matias Velazquez, CNRS, et al.
10:45	Oral presentation-04 THz Raman spectroscopy to probe lattice dynamics and phase transitions in molecular crystals Elena Ferrari, Università di Parma IMEM-CNR, Parma
11:00 - 11:30	COFFEE BREAK
11:30 - 12:45	FUNDAMENTALS OF NUCLEATION AND CRYSTAL GROWTH-02
	Aula Magna Chair/s: Elias Vlieg
11:30	Invited talk-01 Laser-Induced Crystallization Process of an Anthracene Observed by High-Speed Shadowgraphy Yuka Tsuri, Nara Institute of Science and Technology Osaka University
12:00	Oral presentation-02 Spatiotemporal Control of Ice Crystallization in Supercooled Water by Focused Irradiation with Laser Pulses Hozumi Takahashi, Osaka University, et al.
12:15	Oral presentation-03 Polymorph transition-mediated non-classical nucleation and growth in the colloidal heteroepitaxial growth Jun Nozawa, Tohoku University, Institute for Materials Research
12:30	Oral presentation-04 Droplet nucleation on a vicinal surface: temperature-activated transitions of a density dependence Artur Tuktamyshev, University of Milano Bicocca

11:30 - 12:45	MODELLING AND ARTIFICIAL INTELLIGENCE OF CRYSTAL GROWTH PROCESSES-01
	SG-T-1 Chair/s: Natasha Dropka, Toru Ujihara
11:30	Invited talk-01 Data-Driven Automated Control Algorithm for Floating-Zone Crystal Growth Using Reinforcement Learning Shunta Harada, Nagoya University
12:00	Oral presentation-02 Data-Driven Flux-Method Crystal Growth of Inorganic Materials Using Bayesian Predictive Simulation Tetsuya Yamada, Faculty of engineering, Shinshu university, Japan Research Initiative for Supra-Materials, Shinshu university, Japan
12:15	Oral presentation-03 NOMAD Electronic Laboratory Notebook (ELN) to generate Findable and Al-ready Crystal Growth Data Andrea Albino, HU Berlin, et al.
12:30	Oral presentation-04 Ising model-based analysis of the GaN(0001) surface reconstructed structures sampled from Bayesian optimization Akira Kusaba, Kyushu University
11:30 - 12:45	BULK CRYSTAL GROWTH-02
	SG-T-2 Chair/s: Ryan Morrow
11:30	Invited talk-01 Crystal growth and characterization of hexagallate bulk single crystals Christo Guguschev, Leibniz-Institut für Kristallzüchtung (IKZ)
12:00	Oral presentation-02 Growth of Li ₂ ¹⁰⁰ MoO ₄ scintillating crystals by LTG Czochralski technique for neutrinoless double beta-decay search Veronika Grigorieva, Nikolaev Institute of Inorganic Chemistry SB RAS, et al.
12:15	Oral presentation-03 Ca ₃ (TeO ₃) ₂ (MO ₄) (M = Mo, W): Mid-Infrared Nonlinear Optical Tellurates with Ultrawide Transparency Ranges and Super-high Laser Induced Damage Thresholds Qian Wu, Beijing Center for Crystal Research and Development, Key Laboratory of Functional Crystals and Laser Technology, Technical Institute of Physics and Chemistry, Chinese Academy of Sciences
12:30	Oral presentation-04 The effect of chemical doping on a lattice parameter of InP. Dmitry Sokolov, Freiberger Compound Materials

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11:30 - 12:45	OPTICAL CRYSTALS-02
	SG-I-1 Chair/s: Dobrosława Kasprowicz
	Citali/s. Dobiosiawa Naspiowicz
11:30	Invited talk-01
	Multiphonon-assisted lasing beyond the fluorescence spectrum in
	Yb:YCOB crystal Fei Liang, Shandong University
	Tor Elarig, Charlotting Chiversity
12:00	Oral presentation-02
	X-ray diffraction studies on the orientation patterned heteroepitaxial GaP
	and GaAsP to assess the domain fidelity Vladimir Tassev, Air Force Research Laboratory
	Vidualitim Facesty, 7 in February
12:15	Oral presentation-03
	Improvement of ZnGeP ₂ optical quality by investigating growth conditions and high energy electron irradiation
	Charlotte VERNOZY TROUILLET, DMAS/ONERA, Université Paris-Saclay,
	F-92322 Chatillon, France LSI, CEA/DRF/IRAMIS, CNRS, École
	Polytechnique, Institut Polytechnique de Paris, 91120 Palaiseau, France
12:30	Oral presentation-04
	Growth of La ₂ Zr ₂ O ₇ , La ₂ Hf ₂ O ₇ and Lu ₃ TaO ₇ single crystals with high
	melting point by micro-pulling-down method and their optical properties
	Yuui Yokota, Tohoku University, et al.
11:30 - 12:45	NEW METHODS AND TECHNIQUES FOR CRYSTAL GROWTH-02
	SG-I-2
	Chair/s: Christo Guguschev, Jan Pejchal
	Chairs. Childle Cagaschev, Carr Cjonar
11:20	
11:30	Invited talk-01
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11:30 - 12:45	FUNCTIONAL ORVETALS OF
11.50 - 12.45	FUNCTIONAL CRYSTALS-02 SG-II-1
	Chair/s: Alberta Bonnani, Adele Sassella
11:30	Invited talk-01 (Eu,Ca,La)(Fe, Co)As₂ single crystal growth and investigation of physical and superconducting properties Hiraku Ogino, AIST National Institute of Advanced Industrial Science and Technology (AIST), Japan Tokyo University of Science
12:00	Oral presentation-02 Single crystal growth and physical properties of layered oxychalcogenide Sr ₂ ZnCu ₂ (S _{1-x} Se _x) ₂ O ₂ Takahiro Kato, Tokyo university of science National Institute of Advanced Industrial Science and Technology, et al.
12:15	Oral presentation-03 High Pressure – High Temperature solid-state reactions: how to play with the chemistry to tune physical properties in multifunctional materials Chiara Coppi, IMEM-CNR Università degli Studi di Parma, et al.
12:30	Oral presentation-04 High pO ₂ flux growth and characterization of perovskite NdNiO ₃ crystals Junjie Zhang, Shandong University
11:30 - 12:45	ADVANCES IN OBSERVATION AND CHARACTERIZATION METHODS-02
	SG-II-2 Chair/s: Cinzia Giannini, Luke Rhodes
11:30	Invited talk-01 In situ microbeam surface X-ray scattering reveals alternating step kinetics during OMVPE of GaN Guangxu Ju, Peking University
12:00	Oral presentation-02 µLaue diffraction and XEOL to study structure and light emission in materials Joel Eymery, Univ. Grenoble Alpes CEA, IRIG, MEM, NRX, 38000 Grenoble Cedex, France
12:15	Oral presentation-03 Probing Ferroelectricity in Lead Halide Perovskites Using Second Harmonic Generation Microscopy Giorgia Rizzi, KU Leuven
12:30	Oral presentation-04 k-resolved electronic structure of bulk crystals, buried heterostructures and impurity systems by soft-X-ray ARPES

MON, 31 JUL

12:45 - 14:00	IOCG EXECUTIVE COMMITTEE MEETING
12:45 - 14:00	LUNCH
14:00 - 14:45	FRANK PRIZE Aula Magna Chair/s: Giuseppe Falini
	Crystal growth patterns in nature: the science behind the beauty Juan Garcia-Ruiz, Instituto Andaluz de Ciencias de la Tierra

14:45 - 16:00	FUNDAMENTALS OF NUCLEATION AND CRYSTAL GROWTH-03
1 11 10 10100	Aula Magna
	Chair/s: Wenhao Sun
14:45	Invited talk-01 In situ optical spectroscopy of crystallization: One crystal nucleation at a time Takuji Adachi, University of Geneva
15:15	Oral presentation-02 Growth Promotion of Targeted Crystal Faces of Organics Compounds and Proteins by Nano-Processing via Laser Ablation Hiroshi Yoshikawa, Graduate School of Engineering, Osaka University, Japan, et al.
15:30	Oral presentation-03 Heterogeneous two-step crystallization from colloid suspensions: surface geometry and confinement effects on mechanisms and rates Aaron Finney, University College London
15:45	Oral presentation-04 Mechanisms of nucleation and post-nucleation of bismuth tri-iodide onto graphene substrates Laura Fornaro, Universidad de la República, Centro Universitario Regional del Este, Departamento de Desarrollo Tecnológico
14:45 - 16:00	MODELLING AND ARTIFICIAL INTELLIGENCE OF CRYSTAL GROWTH PROCESSES- 02 SG-T-1
	Chair/s: Natasha Dropka, Toru Ujihara
14:45	Invited talk-01 Machine learning applications for crystal growth Kentaro Kutsukake, RIKEN Nagoya University
15:15	Oral presentation-02 Growth of mc-Silicon ingot by DS Process: Experimental and Machine Learning Srinivasan Manikam, Associate Professor
15:30	Oral presentation-03 Optimization method of crystal growth conditions by tacit knowledge (for large-diameter SiC solution growth) TORU UJIHARA, Nagoya University UJ-Crystal RIKEN
15:45	Oral presentation-04 Evaluation of Numerical Modeling on Constitutional Supercooling during Heavily Boron Doped Silicon Single Crystal Growth using Cz Method Yuji Mukaiyama, STR Japan K.K.

14:45 - 16:00	BULK CRYSTAL GROWTH-03 SG-T-2
	Chair/s: Hanna Dabkowska
14:45	Invited talk-01 Numerical analysis of heat and mass transfer of Ga ₂ O ₃ grown by skull melting method Koichi KAKIMOTO, NICHe, Tohoku Univ. JAPAN C&A Co.2, JAPAN RIAM, Kyushu Univ. JAPAN IMR, Tohoku Univ. JAPAN
15:15	Oral presentation-02 Analysis of the Engulfment of Argon Bubbles during Silicon Crystal Growth Jeffrey Derby, University of Minnesota, et al.
15:30	Oral presentation-03 Growth dynamics of lattice dislocations and small-angle grain boundaries in multicrystalline silicon during directional solidification Lu-Chung Chuang, Institute for Materials Research, Tohoku University, et al.
15:45	Oral presentation-04 Optimization of temperature distribution transition in Directional Solidification method without restriction of growth furnace structure Kentaro Kutsukake, Nagoya University /Graduate School of Engineering
14:45 - 16:00	OPTICAL CRYSTALS-03 SG-I-1 Chair/s: Ebrahim Karimi
14:45	Invited talk-01 Design and application of upconversion nanocrystals for sensing and lasing at single particle level Yunfei Shang, Harbin Insitute of Technology
15:15	Oral presentation-02 Growth and Scintillation Properties of Carbazole and <i>p</i> -Terphenyl Shunsuke Kurosawa, Tohoku University Osaka University
15:30	Oral presentation-03 Investigation of the phase diagram of the CsI-LiBr system and fabrication of the eutectic scintillator for thermal neutron detection Rei Sasaki, The Department of Materials Science, Graduate School of Engineering, Tohoku University, Japan The Institute for Materials Research, Tohoku University, Japan
15:45	Oral presentation-04 Growth and characterization of ⁶Lil:Ag crystal scintillators for lunar surface thermal and epithermal neutron detection Hongjoo Kim, Kyungpook National University

14:45 - 15:45	NEW METHODS AND TECHNIQUES FOR CRYSTAL GROWTH-03 SG-I-2
	Chair/s: Christo Guguschev, Jan Pejchal
14:45	Invited talk-01 Recent Progress in MOCVD Technology for PE Device Production Bernd Schineller, AIXTRON SE Dornkaulstrasse 2 52134 Herzogenrath, Germany
15:15	Oral presentation-02 Electrochemical control of crystallization at soft interfaces Franca Jones, Curtin University, Western Australia
15:30	Oral presentation-03 Investigation of shape control criteria for wire fabrication of alloys by the dewetting micro-pulling-down method Rikito Murakami, Institute for Materials Research, Tohoku University C&A Corporation
15:45	Oral presentation-04 - CANCELLED A Very Simple, Pleasant and Trouble-Free Crystal Growth Method: Introduced A Novel ISR Method for Unidirectional Growth Karuppasamy Pichan, Sri Sivasubramaniya Nadar College of Engineering, Chennai-603110, Tamil Nadu, India. Raja Ramanna Centre for Advanced Technology (RRCAT), Indore-452013, Madhya Pradesh, India
14:45 - 15:45	FUNCTIONAL CRYSTALS-03
7 11 10 101 10	SG-II-1 Chair/s: Alberta Bonnani, Adele Sassella
14:45	Invited talk-01 Growth of high quality rare earth iron garnet single crystals by the flux-Bridgman method Hui Shen, Shanghai Institute of Technology
15:15	Oral presentation-02 Growth of Rare Earth Iron Garnet Single Crystals Dharmalingam Prabhakaran, University of Oxford
15:30	Oral presentation-03 Structural Design, Crystal Growth and Optical Properties of Sr2Be2B2O7- type Deep-UV Birefringent Materials Ruixin Guo, Shenzhen Institute for Quantum Science and Engineering, Southern University of Science and Technology International Quantum Academy Beijing Center for Crystal Research and Development, Key Laboratory of Functional Crystals and Laser Technology, Technical Institute of Physics and Chemistry, Chinese Academy of Sciences, Beijing 100190, China
15:45	Oral presentation-04 - CANCELLED Large KTiOPO ₄ -crystal hydrothermally gown from 27 L-autoclave for electro-optical application Haitao Zhou, Tianjin Unieversity of Technology/Guilin Bairay Photoelectric Technology Co., Ltd, et al.

14:45 - 16:00	STRUCTURAL DEFECTS AND IMPURITIES IN CRYSTALLINE MATERIALS-01 SG-II-2 Chair/s: Claudio Ferrari
14:45	Invited talk-01 Laser diode degradation: mechanisms and defects Juan Jimenez, Universidad de Valladolid Valladolid, Spain
15:15	Oral presentation-02 Challenges in growth of nitride semiconductors epi structures: minimizing effects of dislocations and point defects Mike Leszczynski, Institute of High Pressure Physics
15:30	Oral presentation-03 Origin of Surface Defects in Homoepitaxially Grown (010) β-Ga ₂ O ₃ films Mark Goorsky, Department Materials Science and Engineering, University of California Los Angeles
15:45	Oral presentation-04 The influence of point defects present in the different substrates on InGaN/GaN QWs properties and stability at elevated temperatures Mikolaj Grabowski, Institute of High Pressure Physics of the Polish Academy of Sciences
16:00 - 16:30	COFFEE BREAK
16:30 - 18:30	POSTER SESSION 03

TUE, 1	AUG
09:00 - 09:45	PLENARY LECTURE-02 Aula Magna Chair/s: Giuseppe Falini
	From Unraveling Crystal Growth Strategies in Nature to Their Implementation in Synthetic Systems Boaz Pokroy, Technion - Israel Institute of Technology

09:45 - 11:00	FUNDAMENTALS OF NUCLEATION AND CRYSTAL GROWTH-04
	Aula Magna Chair/s: Juan M Garcia-Ruiz
09:45	Invited talk-01 "Seeing is believing" Surface Catalysis in Crystal Nucleation and Epitaxy Masaya Sakakibara, Department of Chemistry, The University of Tokyo
10:15	Oral presentation-02 Growth kinetics of elementary spiral steps on prism faces of ice crystals grown in vapor and their temperature dependence Gen Sazaki, Hokkaido University
10:30	Oral presentation-03 Vapor Growth of ZnSe-based Compound Semiconductors in Low Gravity environment on International Space Station Ching-Hua Su, NASA Marshall Space Flight Center
10:45	Oral presentation-04 Van der Waals SnSe ₂ epitaxial films on Bi ₂ Se ₃ (0001) and Si(111) surfaces Sergei Ponomarev, Rzhanov Institute of Semiconductor Physics Siberian Branch of Russian Academy of Sciences Novosibirsk State University Sobolev Institute of Geology and Mineralogy Siberian Branch of Russian Academy of Sciences, et al.
09:45 - 11:00	MODELLING AND ARTIFICIAL INTELLIGENCE OF CRYSTAL GROWTH PROCESSES- 03 SG-T-1 Chair/s: Natasha Dropka, Toru Ujihara
09:45	Invited talk-01 Fast prediction of transport structures in bulk single crystal growth by Physics Informed Neural Networks Yasunori Okano, Osaka University
10:15	Oral presentation-02 Effect of crystal and crucible rotation on the thermal and oxygen instabilities in a Czochralski process for solar silicon growth Daniel Vizman, West University of Timisoara
10:30	Oral presentation-03 Optimization of the thermal field of 8-inch SiC crystal growth by PVT method with "3 separation heater method" Binjie Xu, State Key Laboratory of Silicon Materials and School of Materials Science and Engineering, Zhejiang University, Hangzhou 310027, China Zhejiang Provincial Key Laboratory of Power Semiconductor Materials and Devices, ZJU-Hangzhou Global Scientific and Technological Innovation Center, Hangzhou 311215, China
10:45	Oral presentation-04 Investigation of the turbulent silicon melt flow in a model geometry under a horizontal magnetic field Andrey Smirnov, Semiconductor Technology Research d.o.o. Beograd

09:45 - 11:00	BULK CRYSTAL GROWTH-04
	SG-T-2 Chair/s: Ryan Morrow
09:45	Invited talk-01 Mg ₂ Si crystal growth by the vertical Bridgman method: scale-up and optimization by modeling and growth experiments Xin Liu, Nagoya University, et al.
10:15	Oral presentation-02 Dislocation Interaction with Faceted Groove at Grain Boundary in Multicrystalline Silicon Fan Yang, Institute for Materials Research, Tohoku University
10:30	Oral presentation-03 On the origin of cracks in thick GaN crystals grown by HVPE Gleb Lukin, Fraunhofer Institute for Integrated Systems and Device Technology IISB, et al.
10:45	Oral presentation-04 Stress analysis of multicrystalline Si with artificial grain boundaries to investigate the generation mechanism of dislocation clusters Haruki Tajika, Graduate School of Engineering, Nagoya University, Japan, et al.
09:45 - 11:00	
09.45 - 11.00	THIN FILMS AND EPITAXIAL GROWTH-01
09.45 - 11.00	THIN FILMS AND EPITAXIAL GROWTH-01 SG-I-1 Chair/s: Fabio Miletto-Granozio
09:45	SG-I-1
	SG-I-1 Chair/s: Fabio Miletto-Granozio Invited talk-01 Effect of different substrates and growth conditions on nucleation and properties of k - and b -Ga ₂ O ₃ thin films grown by MOVPE
09:45	SG-I-1 Chair/s: Fabio Miletto-Granozio Invited talk-01 Effect of different substrates and growth conditions on nucleation and properties of k - and b -Ga ₂ O ₃ thin films grown by MOVPE Roberto Fornari, University of Parma Oral presentation-02 Mist chemical vapor deposition of α-Ga ₂ O ₃ and α-Fe ₂ O ₃ thin films on corundum-structured rh-ITO electrode Kazuki Shimazoe, Department of Electronics, Kyoto Institute of Technology, et

09:45 - 11:00	CRYSTALLINE SOLIDS FOR DRUGS AND PHARMACEUTICALS-01
	SG-I-2
	Chair/s: Tariq Mahmud, Lucia Maini
09:45	Invited talk-01 Artificial neural networks for co-crystal prediction Elias Vlieg, Radboud University
10:15	Oral presentation-02 Challenges, Solutions and Opportunities within Pharmaceutical API Development: Overview and Case Study Peter Kaskiewicz, AstraZeneca
10:30	Oral presentation-03 Effect of impurities on supersaturation control during batch cooling crystallisation of an organic compound Ryan Leeming, School of Chemical and Process Engineering, University of Leeds, UK
10:45	Oral presentation-04 Modular microfluidic platform for solubility measurement, nucleation statistics and polymorph screening of active pharmaceutical ingredients. Mathilde Lambert, CINaM - CNRS - Aix-Marseille Université Sanofi R&D - Global CMC / Synthetics - Early Development France
09:45 - 11:00	OPTICAL CRYSTALS-04
	SG-II-1 Chair/s: Giulio Cerullo
09:45	Invited talk-01 Novel borate-based crystalline materials for efficient generation of red light Mitrabhanu Behera, National Institute of Technology Andhra Pradesh, Andhra Pradesh, India
10:15	Oral presentation-02 Research Progress of Nonlinear Optical Crystal CLBO Shuangshuang Shi, Beijing Sinoma Synthetic Crystals Co., Ltd, , et al.
10:30	Oral presentation-03 Growth and optical properties of Nd:LYSB as a new laser and nonlinear optical borate crystal Alin Broasca, National Institute for Laser, Plasma and Radiation Physics, ECS Laboratory, Romania Doctoral School of Physics, University of Bucharest, Faculty of Physics, Romania
10:45	Oral presentation-04 Synthesis and study of novel dysprosium doped yttrium calcium borate (Dy:Y2CaB10O19) crystalline materials for white LED applications Mitrabhanu Behera, National Institute of Technology Andhra Pradesh, Andhra Pradesh, India

09:45 - 10:45	FUNCTIONAL CRYSTALS-04 SG-II-2 Chair/s: Alberta Bonnani, Adele Sassella
09:45	Invited talk-01 Metal-organic crystals: shaping, uniformity and symmetry breaking Maria Chiara di Gregorio, Department of Chemistry, Sapienza University, Rome, Italy
10:15	Oral presentation-02 Plastic Crystals and Solid-Solutions: From Modulation of the Plastic Transition to the Development of Novel Solid-State Electrolytes simone d'agostino, the University of Bologna
10:30	Oral presentation-03 Electro-optic Effects of Borate Crystals Studied by First Principles Method Rukang Li, Beijing Centre for Crystal Research and Development, Key Laboratory of Functional Crystals and Laser Technology, Technical Institute of Physics and Chemistry, Chinese Academy of Sciences. Beijing 100190, China
10:45	Oral presentation-04 - CANCELLED Effective third harmonic generation based on Ba3(ZnB5O10)PO4 crystal Shihui Ma, Tianjin University of Technology School of Materials Science and Engineering, Linyi University, Linyi 276000, China.
11:00 - 11:30	COFFEE BREAK

11:30 - 12:45	FUNDAMENTALS OF NUCLEATION AND CRYSTAL GROWTH-05 Aula Magna Chair/s: Jim De Yoreo
11:30	Invited talk-01 Dynamic observation of polymorphic phase transition of calcium oxalate crystals; A novel system to elucidate the process and kinetics of urinary stones formation Mihoko Maruyama, Osaka University/ Graduate School of Engineering Kyoto Prefectural University/ Graduate School of Life and Environment Science, et al.
12:00	Oral presentation-02 Effects of additives on the crystallisation of solids contributing to crystal arthritis Franca Jones, Curtin University
12:15	Oral presentation-03 Chiral Crystallization Directed by Superchiral Plasmonic Near-field Force Hiromasa Niinomi, Institute of Multidisciplinary Research for Advanced Materials (IMRAM), Tohoku University
12:30	Oral presentation-04 Silicate Spherulites Rapidly Crystallized from Hypercooled Melt Droplets Katsuo Tsukamoto, Tohoku University
11:30 - 12:45	MODELLING AND ARTIFICIAL INTELLIGENCE OF CRYSTAL GROWTH PROCESSES- 04 SG-T-1 Chair/s: Natasha Dropka, Toru Ujihara
11:30	Invited talk-01 Role of electronic degrees of freedom in adsorption and the dynamics of the growth of semiconductor crystals and layers Stanislaw Krukowski, Institute of High Pressure Physics Polish Academy of Sciences
11:30	Role of electronic degrees of freedom in adsorption and the dynamics of the growth of semiconductor crystals and layers Stanislaw Krukowski, Institute of High Pressure Physics Polish Academy of
	Role of electronic degrees of freedom in adsorption and the dynamics of the growth of semiconductor crystals and layers Stanislaw Krukowski, Institute of High Pressure Physics Polish Academy of Sciences Oral presentation-02 Modeling of Convective Transport in Crystallization of Gallium Nitride by Basic Ammonothermal Method

11:30 - 12:45	BLUK CDYCTAL CDOWTH OF
11.00 12.10	BULK CRYSTAL GROWTH-05 SG-T-2
	Chair/s: Rosalba Fittipaldi
11:30	Invited talk-01
	Czochralski growth of Yb- and Eu-based intermetallic compounds Kristin Kliemt, Goethe Universität Frankfurt
12:00	Oral presentation-02 Crystal growth and magnetic properties of rare-earth(RE) palladium
	silicides, RE₂PdSi₃ Daniel Alexander Mayoh, University of Warwick, et al.
12:15	Oral presentation-03 Crystal growth of multicomponent high entropy rare-earth oxides and
	aluminates
	Mariya Zhuravleva, Department of Materials Science and Engineering, University of Tennessee Scintillation Materials Research Center, University of Tennessee
12:30	Oral presentation-04 Fundamental studies on crystallization and reaching the equilibrium shape
	in basic ammonothermal method
	Tomasz Sochacki, Institute of High Pressure Physics Polish Academy of Sciences
11:30 - 12:45	CRYSTALLIZATION OF ORGANIC AND BIOLOGICAL SYSTEMS-01
	SG-I-1 Chair/s: Simona Fermani, Consiglia Tedesco
11:30	Invited talk-01
	Organic crystallization mechanisms elucidated by electron microscopy Boris Rybtchinski, Weizmann Institute of Science
12:00	Oral presentation-02
	Controlled Crystallization of Centimeter-Size 4HCB Organic Single Crystalline Semiconductors for Novel Radiation Sensor Applications
	Yadong Xu, Northwestern Polytechnical University, China, et al.
12:15	Oral presentation-03
	BSA nanoparticles as nano-bio heterogeneous nucleant for protein crystallization.
	Silvia Fanti, University of Bologna
12:30	Oral presentation-04
	Purification of monoclonal antibody by Membrane Assisted Crystallization Elvira Pantuso, Istituto per la Tecnologia delle Membrane (ITM-CNR)

11:30 - 12:45	COMPOSITE AND HYBRID CRYSTALS-01
	SG-I-2 Chair/s: Abel Moreno, Dritan Siliqi
11:30	Invited talk-01 Cocrystallizing polymers with small molecules: towards a new class of organic supermolecules Dritan Hasa, University of Trieste
12:00	Oral presentation-02 Cocrystal formation and crystal polymorph selection by patchy particles Bogdan Ranguelov, Institute of Physical Chemistry, Bulgarian Academy of Sciences
12:15	Oral presentation-03 Material design and fabrication of a novel optical guiding crystal scintillator Kei Kamada, Tohoku Univ. C&A corporation
12:30	Oral presentation-04 Eutectic Materials for 5G and 6G Technology Hamid Reza Darabian, ENSEMBLE3 Centre of Excellence, ul. Wolczynska 133, 01-919 Warsaw, Poland
11:30 - 12:45	OPTICAL CRYSTALS-05
11:30 - 12:45	OPTICAL CRYSTALS-05 SG-II-1 Chair/s: Carlo Altucci, Dobrosława Kasprowicz
11:30 - 12:45 11:30	SG-II-1
	SG-II-1 Chair/s: Carlo Altucci, Dobrosława Kasprowicz Invited talk-01 Lanthanide activated fluoride nanoparticles as luminescent probes and optical thermometers Adolfo Speghini, NRG, Department of Biotechnology, University of Verona and
11:30	SG-II-1 Chair/s: Carlo Altucci, Dobrosława Kasprowicz Invited talk-01 Lanthanide activated fluoride nanoparticles as luminescent probes and optical thermometers Adolfo Speghini, NRG, Department of Biotechnology, University of Verona and INSTM, RU Verona, Strada Le Grazie 15, I-37134 Verona, Italy. Oral presentation-02 Crystal growth and characterization of Cs ₄ Mg ₃ F ₁₀ prepared by the micropulling-down method

11:30 - 12:45	FUNCTIONAL CRYSTALS-05 SG-II-2 Chair/s: Alberta Bonnani, Adele Sassella
11:30	Invited talk-01 Growth, applications and defect characterizations of α-GeO2 bulk crystals Alexandra Peña Revellez, Université Grenoble Alpes, CNRS, Grenoble INP, Institut Née Université Grenoble Alpes, CNRS, Grenoble INP, SIMaP
12:00	Oral presentation-02 Growth of Mg₂Si thermoelectric crystals with eutectic morphology by unidirectional solidification Naomoto Hayashi, Graduate School of Engineering, Tohoku University, Japan Tohoku UniversityInstitute for Materials Research, Tohoku University, Japan, et al.
12:15	Oral presentation-03 Enhancements on the Performance of Thermoelectric Materials by Directional Solidification Ching-Hua Su, NASA Marshall Space Flight Center
12:30	Oral presentation-04 NiTiO ₃ /TiO ₂ hybrid crystal for efficient overall water splitting Sanjit Saha, ENSEMBLE3 Centre of Excellence, Wolczynska 133, 01-919 Warsaw, Poland

TUE, 1 AUG

12:45 - 14:00	IOCG COUNCIL MEETING
12:45 - 14:00	LUNCH
13:50 - 14:00	INDUSTRIAL TALK: SEMICONDUCTOR TECHNOLOGY RESEARCH D.O.O. BEOGRAD
14:00 - 14:45	Aula Magna Chair/s: Thierry Duffar Contributions to the development of crystal growth technologies Peter Rudolph, Crystal Technology Consulting

14:45 - 16:00	FUNDAMENTALS OF NUCLEATION AND CRYSTAL GROWTH-06
	Aula Magna Chair/s: Matteo Salvalaglio
14:45	Invited talk-01 The Evolution and Morphological Stability of a Particle in a Binary Alloy Melt Mingwen Chen, University of Science and Technology Beijing
15:15	Oral presentation-02 Analysis of Macrostep Interaction via Carbon Diffusion Field in SiC Solution Growth Yuki Nakanishi, Nagoya University, et al.
15:30	Oral presentation-03 Thermodynamic relationship between norsethite [BaMg(CO ₃) ₂] and witherite[BaCO ₃] Harutoshi Asakawa, Graduate School of Sciences and Technology for Innovation Yamaguchi University, et al.
15:45	Oral presentation-04 Observation of phase transition of calcium oxalate in a human kidney stone for elucidation of the stone formation mechanism Uta Michibata, Osaka University, et al.
14:45 - 15:30	THIN FILMS AND EPITAXIAL GROWTH-02 SG-T-1 Chair/s: Gabriele De Luca
14:45	Invited talk-01 - CANCELLED Functional Oxide Thin Films for Applications in Optical, Electronic and Health Wilfrid Prellier, Laboratoire CRISMAT, ENSICAEN, UNICAEN, CNRS UMR 6508, Bd Mal Juin, Caen, 14050 France
14:45	Oral presentation-02 Metal-to-Insulator Transition in Antiferromagnetic SrCrO3 Thin Films Simon Jöhr, Universität Zürich
15:00	Oral presentation-03 Group-IV Ge _{1-x} Sn _x alloys: growth challenge and isothermal heteroepitaxy for electronic, photonic, and energy harvesting applications Omar Concepción, Peter Gruenberg Institute 9 (PGI-9), Forschungszentrum Juelich, 52428 Juelich, Germany
15:15	Oral presentation-04 SrFe _{0.9} Mo _{0.1} O _{3-δ} epitaxial thin films grown by PLD Eugenia Sebastiani, SpLine CRG-BM25 - ESRF ICMM CSIC

14:45 - 16:00	BULK CRYSTAL GROWTH-06
	SG-T-2 Chair/s: Hanna Dabkowska
14:45	Invited talk-01 NOVEL VISIBLE-INFRARED FARADAY CRYSTAL TB ₃ AL ₃ GA ₂ O ₁₂ EXHIBITING SUPERIOR MAGNETO-OPTICAL PERFORMANCE Xiuwei Fu, Shandong University
15:15	Oral presentation-02 Ternary cesium lithium iodide crystals grown by vertical Bridgman method for scintillation applications Robert Kral, Institute of Physics, Czech Academy of Sciences, Cukrovarnicka 10, Prague, Czech Republic
15:30	Oral presentation-03 Non-destructive synchrotron probes of optical floating zone crystal growth: cm-scale grain maps, interfaces, mosaicity, and temperature profiles Peter Khalifah, Brookhaven National Laboratory
15:45	Oral presentation-04 Automation Increases Productivity of Czochralski Crystal Growth in Solar Industry Zhixin Li, Linton Technologies Group
14:45 - 16:00	CRYSTALLIZATION OF ORGANIC AND BIOLOGICAL SYSTEMS-02
	SG-I-1 Chair/s: Simona Fermani, Consiglia Tedesco
14:45	Invited talk-01 Mesocrystalline Ordering and Phase Transformation of Iron Oxide Biominerals in the Ultrahard Teeth of Chitons David Kisailus, University of California at Irvine
15:15	Oral presentation-02 Valorization of waste mussel shells by recovering aragonite and calcite single crystals from the shells Carla Triunfo, Department of Chemistry "Giacomo Ciamician", University of Bologna, Italy. Fano Marine Center, The Inter-Institute Center for Research on Marine Biodiversity, Resources and Biotechnologies, Italy.
	maine Bloarverery, Resources and Blotsen molegies, may.
15:30	Oral presentation-03 One-step hydrothermal transformation of oyster shell Mg-calcite to biomimetic nanocrystalline apatite Jaime Gómez Morales, Laboratorio de Estudios Cristalográficos Instituto Andaluz de Ciencias de la Tierra CSIC-University of Granada

14:45 - 16:00	COMPOSITE AND HYBRID CRYSTALS-02
	SG-I-2 Chair/s: Abel Moreno, Dritan Siliqi
14:45	Invited talk-01 Composite materials in biologically controlled mineralization Linda Pastero, Università degli Studi di Torino
15:15	Oral presentation-02 Biosilicification and biocalcification of membrane fibers mantles of the eggshells of ratite birds and archosaurs reptiles (crocodiles) Nerith Elejalde-Cadena, National Autonomous University of Mexico
15:30	Oral presentation-03 Nonequilibrium synthesis of nature-inspired multicomponent iron salt Simon Lepinay, University of Amsterdam
15:45	Oral presentation-04 Biological Blueprints For Architected Impact Resistant Materials David Kisailus, University of California at Irvine
14:45 - 16:00	OPTICAL CRYSTALS-06
	SG-II-1 Chair/s: Adolfo Speghini
14:45	Invited talk-01 Parametric nonlinear optics with two-dimensional materials Giulio Cerullo, Politecnico di Milano
15:15	Oral presentation-02 Relationship of Single Crystal Growth and Luminescence Properties of Garnet-type Single Crystals for Radiation Dose-Rate Monitoring Systems Daisuke Matsukura, Institute for Materials Research, Tohoku University
15:30	Oral presentation-03 Growth of Large CsLiB₆O₁₀ Crystal from Li-Poor Self-Flux Masashi Yoshimura, Osaka University, et al.
15:45	Oral presentation-04 Development of LYSB and Yb-doped LYSB crystals as new candidates for the next generation of nonlinear optical and/or laser crystals Madalin Greculeasa, National Institute for Laser, Plasma and Radiation Physics, ECS Laboratory, Romania Doctoral School of Physics, University of Bucharest, Faculty of Physics, Romania

14:45 - 16:00	CRYSTALS FOR PHOTOVOLTAICS AND GREEN ENERGY-01
	SG-II-2 Chair/s: Jochen Friedrich, Stefano Rampino
14:45	Invited talk-01 Study of III-V thin films growth directly on silicon by remote-plasma CVD: Towards a reduction in solar cell industrialisation costs Lise Watrin, Ecole Polytechnique Institut Photovoltaïque d'IIe-de-France (IPVF)
15:15	Oral presentation-02 Effect of Cu-doping on crystallization and photovoltaic performance of Sb ₂ Se ₃ thin films. Giulia Spaggiari, Department of Mathematical, Physical and Computer Sciences, University of Parma. Institute of Materials for Electronics and Magnetism (IMEM), CNR.
15:30	Oral presentation-03 Doping Effects of Conductivity Improvement in Anti-perovskite Na ₃ OX Solid Electrolytes Mariko Murayama, Department of Physics, Tokyo University of Science 1-3 Kagurazaka, Shinjuku-ku, Tokyo 162-8601, Japan
15:45	Oral presentation-04 Si-Epitaxy with mixtures of trichlorosilane and silicon tetrachloride precursors at different temperatures Marion Drießen, Fraunhofer-Institut for Solar Energy Systems ISE
16:00 - 16:30	COFFEE BREAK
16:30 - 18:30	POSTER SESSION 02

WED, 2 AUG	
09:00 - 09:45	PLENARY LECTURE-03 Aula Magna Chair/s: Andrea Zappettini
	20 years crystal growth of solar silicon: my serendipity journey Chung-wen Lan, Department of Chemical Engineering, National Taiwan University

09:45 - 10:45	FUNDAMENTALS OF NUCLEATION AND CRYSTAL GROWTH-07
	Aula Magna Chair/s: Laura Fornaro
09:45	Invited talk-01 How mild dissolution can actually promote bulk crystal growththe case of dolomite CaMg(CO3)2 Wenhao Sun, University of Michigan, Ann Arbor
10:15	Oral presentation-02 Effect of the Anticaking Agent FeCN on the Creeping Properties of Alkali Halide Crystals Elias Vlieg, Radboud University
10:30	Oral presentation-03 Conversion of stable crystals to metastable crystals in a solution during temperature cycling Hiroyasu Katsuno, Hokkaido University
10:45	Oral presentation-04 - CANCELLED On fibrous growth during the discontinuous precipitation: A phase-field study Lynda AMIROUCHE, 1Laboratoire de Physique Théorique, Faculté de Physique, U. S. T. H. B., BP 32, El-Alia, Bab
09:45 - 11:00	BULK CRYSTAL GROWTH-07
	SG-T-1 Chair/s: Giuseppe Falini
09:45	Invited talk-01 Soft and deformable hydrated salt crystals under deliquescence Noushine Shahidzadeh, University of Amsterdam/ Institute of Physics
10:15	Oral presentation-02 Chemical textures on rare earth carbonates: an experimental approach to mimic the formation of bastnasite Melanie Maddin, Trinity College Dublin
10:30	Oral presentation-03 Oxalates for non-conventional greenhouse carbon mineralization Linda Pastero, Università degli Studi di Torino
10:45	Oral presentation-04 Transient epitaxial overgrowths in the CaCO ₃ -REECO ₃ OH system formed during mineral replacement reactions Juan Diego Rodriguez-Blanco, Trinity College Dublin, et al.

09:45 - 10:30	CRYSTALLIZATION OF ORGANIC AND BIOLOGICAL SYSTEMS-03					
	SG-T-2 Chair/s: Simona Fermani, Consiglia Tedesco					
09:45	Invited talk-01 - CANCELLED Microdialysis on-chip crystallization of soluble and membrane proteins with the MicroCrys platform and in situ X-ray diffraction case studies Monika Budayova - Spano, Université Grenoble Alpes/Institut de Biologie Structurale					
09:45	Oral presentation-02 Combined in vivo and in vitro studies of BaSO ₄ formation in green alga Spirogyra Natercia Barbosa, Department of Physical Chemistry, University of Geneva Department of Earth and Environmental sciences, University of Geneva					
10:00	Oral presentation-03 Adaptations to unusual environments: spines of sea urchins with cryptic morphologies Devis Montroni, Department of Chemistry "Giacomo Ciamician", Alma Mater Studiorum - University of Bologna, via Selmi 2, 40126, Bologna, Italy					
10:15	Oral presentation-04 Computational investigations of the formation mechanism of bone-like minerals from phospholipids Nilson Kunioshi, Waseda University					
09:45 - 11:00 SEMICONDUCTORS-01						
	SG-I-1 Chair/s: Markus Pristovsek					
09:45	Invited talk-01 A study of iron-doped SiGe growth for thermoelectric applications Sheng-Min Hu, Department of Chemical Engineering, National Taiwan University					
10:15	Oral presentation-02 Effect of oxygen concentration during growth on crystalline quality of β- Ga ₂ O ₃ crystals grown by crucible free growth techniques Isao Takahashi, C & A corporation Tohoku university					
10:30	Oral presentation-03 Crystal Growth and Planar Defects of β-Ga ₂ O ₃ Single Crystal Wenxiang Mu, Shandong University					
10:45	Oral presentation-04 Investigation of factors influencing the zone refining process of very high- purity germanium Pradeep Chandra Palleti, Leibniz-Institute for Crystal Growth (IKZ), Max-Born Str. 2, 12489 Berlin, Germany					

09:45 - 11:00	2D MATERIALS-01
	SG-I-2 Chair/s: Silvia Milita, Joan M. Redwing
09:45	Invited talk-01 Mass-producible graphene replacing Indium Tin-Oxide in OLEDs Zhichao Weng, Queen Mary University of London
10:15	Oral presentation-02 CVD graphene on Ge substrate: how properties are tuned by growth and annealing temperature Luciana Di Gaspare, Dipartimento di Scienze, Università Roma Tre
10:30	Oral presentation-03 Influence of the sapphire surface termination in the PECVD synthesis of graphene Miguel Sinusia Lozano, Nanophotonics Technology Center, Universitat Politècnica de València, et al.
10:45	Oral presentation-04 Synthesis of ZnO/WS ₂ and ZnS/MoS ₂ core-shell nanowires and possible applications Boris Polyakov, Institute of Solid State Physics, University of Latvia, Latvia
09:45 - 11:00	OPTICAL CRYSTALS-07
	SG-II-1 Chair/s: Yunfei Shang
09:45	SG-II-1
09:45 10:15	SG-II-1 Chair/s: Yunfei Shang Invited talk-01 Spatially Structured Optical Beams via Geometrical Phase
	SG-II-1 Chair/s: Yunfei Shang Invited talk-01 Spatially Structured Optical Beams via Geometrical Phase Ebrahim Karimi, University of Ottawa Oral presentation-02 Cyanurates with new types of π-conjugated anions for optical materials Mingjun Xia, Technical Institute of Physics and Chemistry, Chinese Academy of

09:45 - 11:00	TOPOLOGICAL QUANTUM MATERIALS-01			
	SG-II-2 Chair/s: Mario Cuoco, Anna Isaeva			
09:45	Invited talk-01 Crystal growth and characterization of polymorphic PtBi ₂ Saicharan Aswartham, IFW-Dresden			
10:15	Oral presentation-02 Development of a semiconductor-superconductor hybrid 2DEG with in-situ Nb. Sjoerd Telkamp, ETH Zürich, Laboratory of Solid State Physics			
10:30	Oral presentation-03 MBE growth and topological phases of α-Sn epilayers on insulating (001) CdTe/GaAs substrates Valentyn Volobuiev, Institute of Physics PAS/International Research Centre MagTop National Technical University "KhPI"			
10:45	Oral presentation-04 Multiple Dirac points and surface nonlinear optics in topological semimetal HfGe _{0.92} Te Gang Wang, Institute of Physics, Chinese Academy of Sciences University of Chinese Academy of Sciences			
11:00 - 11:30	COFFEE BREAK			
11:30 - 12:45	FUNDAMENTALS OF NUCLEATION AND CRYSTAL GROWTH-08			
	Aula Magna Chair/s: Linda Pastero, Elias Vlieg, Katsuo Tsukamoto			
11:30	Invited talk-01 Harmonic light scattering probes structure and defects during the fast crystallization of ZIF-8 Stijn Van Cleuvenbergen, KULAK Div. KU Leuven			
12:00	Oral presentation-02 Faceted-Rough Surface in the Non-Equilibrium Steady State Near Equilibrium Noriko Akutsu, Osaka Electro-Communication University			
12:15	Oral presentation-03 Effect of crystallization conditions for the enlargement of the size of DNA- functionalized nanoparticles crystals Lidong Zhang, Grad. School of Eng. Nagoya Univ., Japan IMaSS Nagoya Univ., Japan Japan Synchrotron Radiation Research Institute., Japan			
12:30	Oral presentation-04 Molecular Dynamics Simulations of Small Organic Molecules in Confined Spaces Luca Sironi, Università degli Studi di Milano			

11:30 - 12:45	THIN FILMS AND EDITAVIAL CROWTH 02
11100 12110	SG-T-1 Chair/s: Bharat Jalan
11:30	Invited talk-01 Epitaxial p-type Copper Iodide Thin Films with controlled Carrier Concentration grown by Pulsed Laser Deposition Michael Lorenz, University Leipzig, Felix Bloch Institute for Solid State Physics, Semiconductor Physics Group, Leipzig, Germany
12:00	Oral presentation-02 Evaluation of crystal quality of 3C-SiC layers grown on vicinal carbon-face 4H-SiC substrates with various off-orientations and off-angles Hiroyuki Sazawa, National Institute of Advanced Industrial Science and Technology Advanced Power Electronics Research Center
12:15	Oral presentation-03 Grown C onsidering L attice M ismatch and C rystal Q uality and M agneto- O ptical P roperties of Bi smuth and M anganese co-doped Rare Earth Iron Garnet Crystal Anhua Wu, ey Laboratory of Transparent Optical Functional Inorganic Materials, Shanghai Institute of Ceramics, Chinese Academy of Sciences, Shanghai 201899, China Center of Materials Science and Optoelectronics Engineering, University of Chinese Academy of Sciences, Beijing 100049, China
12:30	Oral presentation-04 Surprising Surfactant Properties of Zn in MOVPE Grown III-V Materials Ayse Ozcan Atar, Tyndall National Institute
11:30 - 12:45	BULK CRYSTAL GROWTH-08 SG-T-2 Chair/s: Hanna Dabkowska
11:30	Invited talk-01 High-pressure growth of BaPrO ₃ single crystal Dharmalingam Prabhakaran, University of Oxford
12:00	Oral presentation-02 High-purity single crystal growth of Sm _{1-x} Y _x FeO ₃ using the zone-refining process in an optical float zone furnace Suja Elizabeth Saji, Indian Institute of Science
12:15	Oral presentation-03 Unravelling Superstructure and Electronic Ordering in LiNiO2 bulk single crystals grown by Optical floating zone technique Uthayakumar Sivaperumal, Department of Physics, Royal Holloway, University of London, Egham, TW20 0EX, United Kingdom ISIS Pulsed Neutron and Muon Source, STFC Rutherford Appleton Laboratory, Didcot, Oxfordshire OX11 0QX, United Kingdom, et al.
12:30	Oral presentation-04 Growth and characterization of Dy _(1-x) Sm _(x) MnO ₃ single crystals by optical floating zone technique Anandha babu Govindan, Sri Sivasubramaniya Nadar College of Engineering

11:30 - 12:45	SEMICONDUCTORS-02
	SG-I-1 Chair/s: Siddha Pimputkar
11:30	Invited talk-01 Detailed study of HVPE-GaN doped with silicon Mikolaj Amilusik, Institute of High Pressure Physics Polish Academy of Sciences
12:00	Oral presentation-02 High electron density of Sn-doped GaN layer by halide vapor phase epitaxy Kansuke Hamasaki, Department of Electronics, Nagoya University, et al.
12:15	Oral presentation-03 Characteristics of high order silane-based Si and SiGe epitaxial growth under 600°C Dongmin Yoon, Yonsei University, Seoul, Repulic of Korea
12:30	Oral presentation-04 Suppression of Inclusions in GaN Crystals Formed During Na-Flux Growth Through the Flux-Film-Coated Technique Masayuki Imanishi, Graduate School of Engineering, Osaka University
11:30 - 12:45	2D MATERIALS-02
	SG-I-2 Chair/s: Silvia Milita, Joan M. Redwing
11:30	Invited talk-01 Spatially Controlled Growth of 2D Materials Zakaria Al Balushi, University of California, Berkeley
12:00	Oral presentation-02 Elemental Phosphorus Single Crystals: Growth and Application Qingfeng Yan, Department of Chemistry, Tsinghua University
12:15	Oral presentation-03 Photoluminescent Properties in 2D (C ₆ H ₅ CH ₂ NH ₃) ₂ (Pb,Mn)Br ₄ Layered Metal Halide Marta Campolucci, University of Genoa
12:30	Oral presentation-04 Air passivation effect on two-dimensional InSe crystals and design for high-quality Schottky junctions Qinghua Zhao, Northwestern Polytechnical University/School of Materials Science and Engineering

WED, 2 AUG

11:30 - 12:45	CRYSTALS FOR PHOTOVOLTAICS AND GREEN ENERGY-02				
	SG-II-1 Chair/s: Jochen Friedrich, Stefano Rampino				
11:30	Invited talk-01 Heteroepitaxial growth of ZnTiN₂ photoabsorbers on GaN for photoelectrochemical CO₂ reduction application John Mangum, National Renewable Energy Laboratory, et al.				
12:00	Oral presentation-02 Flux growth of (Oxy)nitride and Oxysulfide Crystals in an Ammonia Atmosphere Katsuya Teshima, Research Initiative for Supra-Materials, Shinshu university, Japan Faculty of engineering, Shinshu university, Japan Verne Crystal Inc., Japan				
12:15	Oral presentation-03 X-ray topographic characterization of structural defects in thick epitaxial silicon for solar cells Paul Wimmer, Fraunhofer Institute for Integrated Systems and Device Technology IISB, Department Materials, Schottkystrasse 10, Erlangen, 91058, Germany				
12:30	Oral presentation-04 Perfect single crystals of novel chalcogenides for photovoltaics, grown by chemical vapor transport Yvonne Tomm, Helmholtz-Zentrum Berlin				
11:30 - 12:45	TOPOLOGICAL QUANTUM MATERIALS-02				
	SG-II-2 Chair/s: Mario Cuoco, Anna Isaeva				
11:30	Invited talk-01 Crystal growth of candidate materials for topological Kondo semimetals Andrey Prokofiev, Technische Universitaet Wien Institute of Solid State Physics				
12:00	Oral presentation-02 Searching for ideal Bi-system topological insulator, Pb-system topological crystalline insulator and their topological superconductor genda gu, Brookhaven National Laboratory				
12:15	Oral presentation-03 Crystal Growth, Structure, and Magnetism of the 2D Equilateral Triangular Lattice Fluorides Shu Guo, Shenzhen Institute for Quantum Science and Engineering, Southern University of Science and Technology, Shenzhen 518055, China International Quantum Academy, Shenzhen 518048, China				
12:30	Oral presentation-04 3D Topological Insulator eutectic heterostructures: enabled by crystal growth Kingshuk Bandopadhyay, ENSEMBLE3 Centre of Excellence, Wolczynska 133, 01-919 Warsaw, Poland, et al.				

WED, 2 AUG

12:45 - 14:00	LUNCH
14:00 - 18:30	EXCURSION

THU, 3	AUG
09:00 - 09:45	PLENARY LECTURE-04 Aula Magna Chair/s: Geetha Balakrishnan
	Selective area epitaxy for next generation quantum computing and photovoltaics Anna Fontcuberta i Morral, EPFL

09:45 - 11:00	FUNDAMENTALS OF NUCLEATION AND CRYSTAL GROWTH-09
	Aula Magna Chair/s: Linda Pastero, Elias Vlieg
09:45	Invited talk-01 Rational Reduction of Computationally Predicted Crystal Energy Landscapes with Molecular Dynamics Matteo Salvalaglio, University College London
10:15	Oral presentation-02 A universal model of bulk GaN growth Tomasz Sochacki, Institute of High Pressure Physics Polish Academy of Sciences, et al.
10:30	Oral presentation-03 Modelling crystallization: When interfacial velocity depends on the expiring supersaturation Vesselin Tonchev, Faculty of Physics, Sofia University, 1164 Sofia, Bulgaria
10:45	Oral presentation-04 First-principles analysis of the activation energy of solute-additive bonds in the solvent of SiC solution growth Shota Seki, Nagoya University, et al.
09:45 - 11:00	THIN FILMS AND EPITAXIAL GROWTH-04
	SG-T-1 Chair/s: Michael Lorenz
09:45	Invited talk-01 Free-Standing Epitaxial SrTiO3 Nanomembranes via Remote Epitaxy using Hybrid Molecular Beam Epitaxy Bharat Jalan, University of Minnesota
10:15	Oral presentation-02 Charge-Transfer Engineering at Polar Double-Perovskite/Perovskite Interfaces Gabriele De Luca, University of Zurich, Switzerland Instituto de Ciencia de Materiales de Barcelona (ICMAB-CSIC), et al.
10:30	Oral presentation-03 Bandgap study of MBE grown {CdO/MgO} superlattices Abinash Adhikari, Institute of Physics, Polish Academy of Sciences, Al. Lotnikow, 32/46, 02-668, Warsaw, Poland., et al.
10:45	Oral presentation-04 Epitaxial growth of insulating oxides on germanium substrates (001) by pulsed laser deposition Ana Garcia-Prieto, BM25-SpLine The Spanish CRG Beamline at the European Synchrotron Radiation Facility, CS40220 38043 Grenoble Cedex 9 France ICMM-CSIC Materials Science Institute of Madrid, Sor Juana Ines de la Cruz Cantoblanco 28049 Madrid España

09:45 - 11:00	BULK CRYSTAL GROWTH-09				
	SG-T-2 Chair/s: Ryan Morrow				
09:45	Invited talk-01 Optimization of single-crystal growth of the quantum spin liquid candidat NdTa ₇ O ₁₉ by flux method Lia Šibav, Jožef Stefan Institute, Jamova cesta 39, 1000 Ljubljana, Slovenia Jožef Stefan International Postgraduate School, Jamova cesta 39, 1000 Ljubljana, Slovenia				
10:15	Oral presentation-02 Growth and characterization of high quality La₂CoO_{4.25} single crystals Monica CERETTI, CNRS / Institut Charles Gerhardt Montpellier (ICGM)				
10:30	Oral presentation-03 Crystal growth, phase stability and structural transition of orthorhombic Sr ₂ TiO ₄ Enrico Giannini, University of Geneva				
10:45	Oral presentation-04 Floating-zone growth of single-crystal olivine (Mg₁-xFex)₂SiO₄ Yong Liu, Crystal Growth Facility, Institute of Physics, École Polytechnique Fédérale de Lausanne, CH-1015 Lausanne, Switzerland College of Humanities, École Polytechnique Fédérale de Lausanne, CH-1015 Lausanne, Switzerland				
09:45 - 10:45	SEMICONDUCTORS-03				
	SG-I-1 Chair/s: Jeffrey Derby				
09:45	Invited talk-01 Computational Fluid Dynamics modeling of a Novel High-Pressure Spatial				
	Chemical Vapor Deposition Reactor (HPS-CVD) Design for Growth of Indium-Containing Nitrides Siddha Pimputkar, Department of Materials Science and Engineering, Center for Photonics and Nanoelectronics, Lehigh University, Bethlehem, PA 18015, USA				
10:15	Chemical Vapor Deposition Reactor (HPS-CVD) Design for Growth of Indium-Containing Nitrides Siddha Pimputkar, Department of Materials Science and Engineering, Center for				
10:15	Chemical Vapor Deposition Reactor (HPS-CVD) Design for Growth of Indium-Containing Nitrides Siddha Pimputkar, Department of Materials Science and Engineering, Center for Photonics and Nanoelectronics, Lehigh University, Bethlehem, PA 18015, USA Oral presentation-02 Growth and thermal properties of InSe crystal by using the ground simulation apparatus of China space station				

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Oral presentation-04 - CANCELLED

Growth of High Resistive Cd_{0.85}Mn_{0.15}Te Single Crystal Using Vertical Bridgman Method for Ambient Temperature Gamma-Ray Detectors Manivel Rajan, Department of Physics, Sri Sivasubramaniya Nadar College of Engineering, Chennai, India

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09:45 - 11:00	2D MATERIALS-03
	SG-I-2 Chair/s: Zakaria Y. Al Balushi
09:45	Invited talk-01 Two-Dimensional Xenes: Synthesis, Processing, and Manipulation Alessandro Molle, Consiglio Nazionale delle Ricerche (CNR), Istituto per la Microelettronica e Microsistemi (IMM)
10:15	Oral presentation-02 X-ray quantitative investigation of <i>in situ</i> grown 2D Transition metal dichalcogenide TiS ₂ prepared by hybrid ALD/MLD Ashok Kumar Yadav, Synchrotron SOLEIL, Beamline SIRIUS, L'Orme des Merisiers, Saint-Aubin, F-91192, Gif sur Yvette, France, et al.
10:30	Oral presentation-03 Bismuth tri-iodide – Graphene 2D material Laura Fornaro, Universidad de la República/Centro Universitario Regional del Este/ Departamento de Desarrollo Tecnológico
10:45	Oral presentation-04 Magnetic spin textures in intercalated transition metal dichalcogenides. Daniel Mayoh, University of Warwick
09:45 - 11:00	SURFACES AND INTERFACES-01
	SG-II-1
	Chair/s: Raffaella Calarco, Letizia Savio
09:45	
09:45 10:15	Chair/s: Raffaella Calarco, Letizia Savio Invited talk-01 Epitaxial Rules for van der Waals Epitaxy from (GeTe) _m (Sb ₂ Te ₃) _n Phase Change Material Alloys Fabrizio Arciprete, Department of Physics, University of Rome Tor Vergata, Italy
	Invited talk-01 Epitaxial Rules for van der Waals Epitaxy from (GeTe) _m (Sb ₂ Te ₃) _n Phase Change Material Alloys Fabrizio Arciprete, Department of Physics, University of Rome Tor Vergata, Italy Paul-Drude-Institut für Festkörperelektronik, Berlin, Germany Oral presentation-02 Coherent X-ray measurement of local step-flow propagation during polycrystalline organic semiconductor thin film growth with desorption

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09:45 - 11:00	GROWTH AT THE NANOSCALE: NANOCRYSTALS, NANOWIRES, NANOMATERIALS-02
	SG-II-2 Chair/s: Richard Noetzel
09:45	Invited talk-01 MOVPE self-assembly and nano-scale properties of III-V core-(multi)shell nanowires for photonics and photovoltaics Paola Prete, IMM-CNR, et al.
10:15	Oral presentation-02 Pushing group IV epitaxy by means of UHV-CVD: high-quality Ge/SiGe heterostructures for integrated photonic devices Monica De Seta, Dipartimento di Scienze Università Roma Tre, Rome Italy
10:30	Oral presentation-03 Femtosecond laser induced periodic surface structuring of Bi ₂ Te ₃ crystal Jijil JJ Nivas, Università di Napoli Federico II CNR-SPIN, UOS Napoli
10:45	Oral presentation-04 Directional growth of antimony triselenide by molecular beam epitaxy Piotr Wojnar, Institute of Physics Polish Academy of Sciences
11:00 - 11:30	COFFEE BREAK
11:30 - 12:45	BULK CRYSTAL GROWTH-10
	Aula Magna
	Chair/s: Rosalba Fittipaldi
11:30	Invited talk-01 Novel photonic materials enabled by crystal growth Dorota Pawlak, ENSEMBLE3 Centre of Excellence, Poland
12:00	Oral presentation-02 Hydrothermal growth of synthetic Rouaite (Cu ₂ (NO ₃)(OH) ₃): A frustrated S=1/2 triangular-lattice magnet Aswathi Mannathanath Chakkingal, INSTITUTE OF SOLID STATE AND MATERIALS PHYSICS, TU DRESDEN
12:15	Oral presentation-03 Advances in VGF Crystal Growth of Cd _{1-x} Zn _x Te _{1-y} Se _y Alloys José Luis Plaza, Crystal Growth Laboratory, Department of Materials Science, Faculty of Science, University Autónoma of Madrid, Spain
12:30	Oral presentation-04 In-situ determination of crystal-melt interface shape evolutions via probing growth interface electromotive force Yunzhong Zhu, Sun Yat-Sen University

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11:30 - 12:45	TOPOLOGICAL QUANTUM MATERIALS-03 SG-T-1 Chair/s: Mario Cuoco, Anna Isaeva
11:30	Invited talk-01 Design of new topological materials Carmine Autieri, International Research Centre MagTop, Institute of Physics, Polish Academy of Sciences, Aleja Lotników 32/46, PL-02668 Warsaw, Poland
12:00	Oral presentation-02 Bismuth chalcogenides topological insulators crystals grown by optical floating zone technique Anita Guarino, CNR-SPIN Salerno
12:15	Oral presentation-03 Effects of Fe Deficiency and Co Substitution in Single Crystals of Fe ₃ GeTe ₂ Daniel Mayoh, University of Warwick
12:30	Oral presentation-04 Crystal growth and structural variations of the perspective magnetic topological insulators Mn _{1+ x} Sb _{2-2x/3} Te ₄ (MST) Ekaterina Kochetkova, Institute of Solid State Research, Leibniz IFW Dresden, Germany Technische Universität Dresden, Germany
11:30 - 12:45	THIN FILMS AND EPITAXIAL GROWTH-05
	SG-T-2 Chair/s: Luca Pellegrino
11:30	Invited talk-01 Novel (EuIn)As/InAsSb Nanowires Grown by MBE Hadas Shtrikman, Weizmann Institute of Science Polish Academy of Science Bar-Ilan University
12:00	Oral presentation-02 Free-standing InSb nanostructures: growth, morphology control and electrical characterization Lucia Sorba, NANO-CNR
12:15	Oral presentation-03 Growth of Aluminum Nitride Thin Films by Thermal Laser Epitaxy Dong Yeong Kim, Max Planck Institute for Solid State Research
12:30	Oral presentation-04 Surface Stability of Reconstructions on BAs(001) Surface: An Ab Initio-Based ApproachSurface Stability of Reconstructions on BAs(001) Surface:

11:30 - 12:45	SEMICONDUCTORS-04
	SG-I-1 Chair/s: Roberto Fornari
11:30	Invited talk-01 Growth of AIP_yN_{1-y} on GaN by Metal-Organic Vapour Phase Epitaxy Markus Pristovsek, Nagoya University
12:00	Oral presentation-02 Thermodynamic Analysis of Oxide Vapor Phase Epitaxy of GaN Yuki Sakurai, Osaka University, et al.
12:15	Oral presentation-03 Origins of Epitaxial Surface Haze on GaN Substrates for kV Power Devices Mark Goorsky, Materials Science and Engineering, University of California Los Angeles, USA
12:30	Oral presentation-04 Preliminary studies on halide vapor phase epitaxy of AlGaN alloy on GaN substrates Tomasz Sochacki, Institute of High Pressure Physics Polish Academy of Sciences, et al.
11:30 - 12:45	2D MATERIALS-04
11:30 - 12:45	2D MATERIALS-04 SG-I-2 Chair/s: Alessandro Molle
11:30 - 12:45 11:30	SG-I-2
	SG-I-2 Chair/s: Alessandro Molle Invited talk-01 IN SITU Characterisation of Graphene Growth on Liquid Metal Catalysts by Chemical Vapour Deposition
11:30	SG-I-2 Chair/s: Alessandro Molle Invited talk-01 IN SITU Characterisation of Graphene Growth on Liquid Metal Catalysts by Chemical Vapour Deposition Valentina Belova, European Synchrotron Radiation Facility - ESRF, et al. Oral presentation-02 Growth of high purity CVD-grown h-BN using B ₂ H ₆ and NH ₃ Hisashi Yamada, The National Institute of Advanced Industrial Science and

11:30 - 12:45	SURFACES AND INTERFACES-02
	SG-II-1 Chair/s: Raffaella Calarco, Letizia Savio
11:30	Invited talk-01 Interfacing doped graphene with metal surfaces or molecular layers. Cristiana Di Valentin, University of Milano Bicocca
12:00	Oral presentation-02 Near Ambient Pressure reaction under graphene cover on Ni(111) Giovanni Carraro, CNR-IMEM Genova
12:15	Oral presentation-03 Low energy electronic structure in strontium ruthenates: from surface distortions to magnetic-field control of the electronic structure Luke Rhodes, University of St Andrews
12:30	Oral presentation-04 Cu-phthalocyanine long range ordered bulk growth due to the weak interaction with highly oriented pyrolytic graphite Daniele Paoloni, Università degli studi Roma Tre
11:30 - 12:45	Growth at the nanoscale: nanocrystals, nanowires, nanomaterials-03 SG-II-2 Chair/s: Francesco Montalenti
11:30	Invited talk-01 New Insights into Surfactant and Doping Effects in GaAs Nanowire Growth Gregor Koblmüller, Walter Schottky Institut School of Natural Sciences Technical University of Munich
12:00	Oral presentation-02 Surfactant-mediated Selective Area Growth of Germanium Nanowires. Santhanu Panikar Ramanandan, Institute of Materials, Ecole Polytechnique Fédérale de Lausanne (EPFL), Switzerland
12:15	Oral presentation-03 Nanocrystal growth of weak acid derivatives driven by acid-base neutralization Arnaud Magrez, Crystal Growth Facility Ecole Polytechnique Fédérale de Lausanne - EPFL
12:30	Oral presentation-04 Interplay between crystal structure and optical response in Plateau– Rayleigh Zn₂GeO₄/SnO₂ heterostructures Jaime Dolado, European Synchrotron Radiation Facility (ESRF)

THU, 3 AUG

12:45 - 14:00	LUNCH
13:00 - 14:30	ENCG COUNCIL MEETING
13:50 - 14:00	INDUSTRIAL TALK: PHOTONIC SCIENCE AND ENGINEERING
14:00 - 14:45	SCHIEBER PRIZE Aula Magna Chair/s: Jeffrey Derby Bharat Jalan, University of Minnesota
14:45 - 16:00	IOCG GENERAL ASSEMBLY
16:00 - 16:30	COFFEE BREAK
16:00 - 17:00	IOCG EXECUTIVE COMMITTEE MEETING
16:30 - 18:30	POSTER SESSION 03

FRI, 4 A	NUG
09:00 - 09:45	PLENARY LECTURE-05
	Aula Magna Chair/s: Antonio Vecchione
	Oxide interfaces: a versatile platform for material design and ultrafast light control
	Andrea Caviglia, Department of Quantum Matter Physics, University of Geneva, 24 Quai Ernest Ansermet, Geneva CH-1211, Switzerland

09:45 - 11:00	THIN FILMS AND EPITAXIAL GROWTH-06
	Aula Magna Chair/s: Fabio Miletto-Granozio
00.45	Invited talls 04
09:45	Invited talk-01 The role of epitaxy in microelectromechanical systems made with transition metal oxide films Luca Pellegrino, CNR-SPIN
10:15	Oral presentation-02 Fabrication of face-to-face annealed sputter-deposited AIN templates with screw-dislocation densities of 10³-10⁴ cm⁻² Hideto Miyake, Mie University
10:30	Oral presentation-03 Atomically sharp domain walls in epitaxial CuMnAs Filip Krizek, Institute of Physics of the Czech Academy of Sciences
10:45	Oral presentation-04 Growth of Commensurately Strained KTaO ₃ by Suboxide Molecular-Beam Epitaxy Tobias Schwaigert, Platform for the Accelerated Realization, Analysis, and Discovery of Interface Materials (PARADIM), Cornell University, Ithaca, NY 14853, USA Department of Materials Science and Engineering, Cornell University, Ithaca, NY 14853, USA
09:45 - 11:00	2D MATERIALS-05
	SG-T-1 Chair/s: Raffaella Calarco
09:45	Invited talk-01 Effect of pre-anneal chemistry on the growth and properties of epitaxial MoS ₂ on sapphire Nicholas Trainor, The Pennsylvania State University
10:15	Oral presentation-02 Scalable growth of atomically-thin MoS2 layers in conventional MOCVD system using molybdenum oxychloride as the molybdenum source. Xu Yang, Nagoya University
10:30	Oral presentation-03 Spectroscopic Ellipsometry for In Situ Monitoring of MoS ₂ Growth at the Sub-Monolayer Limit Thomas McKnight, The Pennsylvania State University
10:45	Oral presentation-04 Impact of chemistry on the interface with substrate of MoS₂ nanosheets grown by ambient pressure chemical vapor deposition Alessio Lamperti, CNR-IMM, Unit of Agrate Brianza

09:45 - 11:00	GROWTH AT THE NANOSCALE: NANOCRYSTALS, NANOWIRES, NANOMATERIALS-04
	SG-T-2 Chair/s: Stefano Sanguinetti
09:45	Invited talk-01 Two topics on InGaN-based photoelectrochemical sensors Richard Noetzel, South China Normal University
10:15	Oral presentation-02 Growth of Doped ZnO:GO hybrid nanostructure for piezoelectric wearable sensors and energy harvesters Binay Kumar, University of Delhi
10:30	Oral presentation-03 Red emission thin nanocolumns with diameters less than 200 nm prepared by nano-template selective area growth Shunsuke Kudo, Sophia University
10:45	Oral presentation-04 Cathodoluminescence of InP-InGaP Nanowires Irene Mediavilla, Universidad de Valladolid, Valladolid, Spain
09:45 - 11:00	SEMICONDUCTORS-05
	SG-I-1 Chair/s: Mark Goorsky
09:45	Invited talk-01 Comparative Etching Study of Dislocations in Bulk GaN grown by HVPE, Na-Flux and Ammonothermal method Bhavpreeta Pratap Charan, Graduate School of Engineering, Osaka University
10:15	Oral presentation-02 β-Ga ₂ O ₃ thin films grown by Pulsed Electron Deposition Stefano Rampino, IMEM-CNR University of Parma, et al.
10:30	Oral presentation-03 Macrostep flow behavior in 4H-SiC solution growth with different solvent compositions and surface orientations Takeshi Mitani, National Institute of Advanced Industrial Science and Technology
10:45	Oral presentation-04 Understanding Transport and Kinetic Effects during High-Pressure, High-Temperature (HPHT) Growth of Single-Crystal Diamond Jeffrey Derby, University of Minnesota, et al.

09:45 - 11:00	STRUCTURAL DEFECTS AND IMPURITIES IN CRYSTALLINE MATERIALS-02
	SG-I-2 Chair/s: Claudio Ferrari, Jean-Pierre Landesman
09:45	Invited talk-01 Methods for Nanoscale Strain and Stress Mapping in Thin Films Jozef Keckes, Montanuniversität Leoben
10:15	Oral presentation-02 Influence of growth process and crystal defects on sapphire brittleness Thierry Duffar, Grenoble Institute of Technology
10:30	Oral presentation-03 Thermal equilibrium point defects in Si Kentaro Kutsukake, Tohoku University
10:45	Oral presentation-04 Methodology of line dislocation density mapping in aluminum bulk crystals using high energy X-ray transmission topography for quality control in crystal growth Roland Weingärtner, Fraunhofer Institute for Integrated Systems and Device Technology IISB
11:00 - 11:30	COFFEE BREAK
11:30 - 12:45	THIN FILMS AND EPITAXIAL GROWTH-07
	Aula Magna Chair/s: Lucia Sorba
11:30	Invited talk-01 MBE growth of terahertz quantum cascade lasers – the challenges and opportunities of working with the GaAs-AlGaAs materials system Edmund Linfield, University of Leeds
12:00	Oral presentation-02 Low temperature growth of magnesium gallate crystalline films Qixin GUO, Saga University
12:15	Oral presentation-03 Structural properties of ultra-thin Bi₂Te₃ topological insulator on GaAs(100) Sukarno Ferreira, Departamento de Física, Universidade Federal de Viçosa, Brazil
12:30	Oral presentation-04 Long-range magnetic order in Mn₂GaC films studied by NMR Marek Wójcik, Institute of Physics, Polish Academy of Sciences

11:30 - 12:30	2D MATERIALS-06
	SG-T-1 Chair/s: Nicholas Trainor
11:30	Invited talk-01 Transformation of Epitaxial Gallium Telluride Hexagonal Phase into Two-Dimensional Single Crystal Monoclinic Raffaella Calarco, Walter-Schottky-Institut and TUM School of Natural Sciences, Technische Universität München, Am Coulombwall 4, 85748 Garching, Germany Dipartimento di Fisica, Università di Roma "Tor Vergata", Via della Ricerca Scientica 1, 00133, Rome, Italy CNR Institute for Microelectronics and Microsystems (IMM), Consiglio nazionale delle ricerche (CNR), Via del Fosso del Cavaliere 100, 00133, Rome, Italy
12:00	Oral presentation-02 Novel quasicrystalline approximants in two-dimensional oxides Vincent Fournée, Institut Jean Lamour, CNRS -University of Lorraine
12:15	Oral presentation-03 Graphene nucleation on (100)Si using toluene as carbon precursor: A DFT study on early-decomposition steps and anthracene formation Nico Lovergine, IMM-CNR, et al.
12:30	Oral presentation-04 - CANCELLED Tuning of the topological Hall effect in A _x RhO ₂ (A=K, Rb, and Cs) crystals and realizing metastable van der Waals crystalline RhO ₂ magnet by Topochemical method Shuhua Yao, Nanjing university
11:30 - 12:45	GROWTH AT THE NANOSCALE: NANOCRYSTALS, NANOWIRES, NANOMATERIALS-05
	SG-T-2 Chair/s: Paola Prete
11:30	Invited talk-01 Modeling growth of epitaxial nanostructures by continuum methods and machine learning Francesco Montalenti, Università di Milano-Bicocca
12:00	Oral presentation-02 Growth of metal oxide semiconductor microcrystals by optical vapor supersaturated precipitation: mechanism, equipment and applications Yinzhou Yan, Beijing University of Technology
12:15	Oral presentation-03 Evolution of disorder in crystalline structures between single crystal and polycrystal via chemical and physicochemical approaches Hiroaki Imai, Keio University
12:30	Oral presentation-04 A Growth Model for Selective Area Epitaxy of Horizontal GaAs Nanoridges by MOVPE Valerio Piazza, Ecole Polytechnique Fédérale de Lausanne - EPFL

11:30 - 12:45	INDUSTRIAL CRYSTAL GROWTH TECHNOLOGY AND EQUIPMENT-01
	SG-I-1 Chair/s: Jaime Gómez-Morales, Jose Luis Plaza
11:30	Invited talk-01 New cold crucible technology for single crystal growth Kader ZAIDAT, 1Univ. Grenoble Alpes, SIMAP, F-38000 Grenoble, France
12:00	Oral presentation-02 Scaling bulk crystal growth processes between industry and research Kaspars Dadzis, Leibniz Institute for Crystal Growth (IKZ)
12:15	Oral presentation-03 Crystal orientation quantification in less than 10 seconds Lars Grieger, MalvernPanalytical B.V.
12:30	Oral presentation-04 New developments of KRIST <i>MAG</i> ® technology for improved semiconductor crystal growth Christiane Frank-Rotsch, Leibniz-Institut für Kristallzüchtung
11:30 - 12:45	STRUCTURAL DEFECTS AND IMPURITIES IN CRYSTALLINE MATERIALS-03 SG-I-2 Chair/s: Claudio Ferrari
11:30	Invited talk-01 Spatially resolved luminescence properties of quantum well etched microstructures Jean-Pierre Landesman, University Rennes
12:00	Oral presentation-02 Heavy ion irradiation introduced defects in CdZnTe crystals and their effects on carrier transport properties Lingyan Xu, Northwestern Polytecnnical University
12:15	Oral presentation-03 Ultraviolet emission properties of undoped and indium-doped bulk zinc oxide single crystals irradiated with gamma rays Keito Shinohara, Institute of Laser Engineering, Osaka University
12:30	Oral presentation-04 Generation and Expansion of Stacking Faults in Physical Vapor Transport grown 4H-SiC Single-crystals Rong Wang, Zhejiang University
12:45 - 13:00	CLOSING
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POSTER SESSIONS

MON, 31 JUL - POSTER SESSION 01

16:30 - 18:30

Poster Area

Poster presentation-01

A study on the influence of crystal structure and its effects on Li diffusion in Li_{0.29}La_{0.57}TiO₃ single crystal grown by optical floating zone technique Uthayakumar Sivaperumal, Department of Physics, Royal Holloway, University of London, Egham, TW20 0EX, United Kingdom | ISIS Pulsed Neutron and Muon Source, STFC Rutherford Appleton Laboratory, Didcot, Oxfordshire OX11 0QX, United Kingdom

Poster presentation-02

Development and Characterization of (1-x)Bi(Mg2/3Sb1/3)O3 – (x)PbTiO3 Ceramics for Energy-Storage Applications

Aravinthkumar Padmanaban, Oxide Single Crystals Group, Centre of Excellence, ENSEMBLE3 Sp. Z O. O. ul, Wolczynska 133, 01-9191 Warsaw, Poland.

Poster presentation-03

Growth and dielectric properties of Nb₂O₅ single crystal by the optical floating zone method

Yijian Jiang, Institute of Laser Engineering, Faculty of Materials and Manufacturing, Beijing University of Technology, Beijing 100124, China | Institute of Matter Science, Beijing University of Technology, Beijing 100124, China | College of Applied Sciences, Beijing University of Technology, Beijing 100124, P. R. China

Poster presentation-04

Single Crystal Growth and Characterization of Pyroelectric L-arginine Dibromide Monohydrate (LADB)

Ruzan Sukiasyan, Institute of Applied Problems of Physics, NAS of Armenia, et al.

Poster presentation-05

Growth and Improved Properties Single Crystal α –LiIO $_3$ Doped with Amino Acids

Ruzan Sukiasyan, Institute of Applied Problems of Physics, NAS of Armenia

Poster presentation-06

Experimental and Numerical Investigation of Photoluminescence in Rare-earth Doped LiBa₁₂(BO₃)₇F₄ (LBBF) crystals

Bekker Tatyana, Sobolev Institute of Geology and Mineralogy, Siberian Branch of Russian Academy of Sciemces, Novosibirsk, Russia | Novosibirsk State University, Novosibirsk, Russia

Poster presentation-07

Influence of the ionic radius of the stabilizing oxide on the crystal structure and mechanical characteristics of tetragonal crystals of solid solutions of ZrO2-R2O3 (R- Y, Gd, Sm)

Artem Chislov, Prokhorov General Physics Institute of RAS | National University of Science and Technology «MISIS»

Poster presentation-08

Neutron and x-ray scattering study of phonon dispersion and diffuse scattering in (Na,Bi)TiO3-xBaTiO3 single crystals near the morphotropic phase boundary

Chengtao Luo, Shanghai Jiaotong University

Poster presentation-09

Growth of Bismuth Palladium single crystals by optical floating zone technique

Raja Arumugam, CNR-SPIN, University of Salerno, Italy

Poster presentation-10

Spontaneous off-stoichiometry as the knob to control dielectric properties of La₃Te₄

Muhammad Rizwan Khan, Centre of Excellence ENSEMBLE3 Sp. z o. o., Wolczynska Str. 133, 01-919, Warsaw, Poland

Poster presentation-11

Real gapped metals: when energy lowering symmetry breaking does not open the gap

Harshan Reddy Gopidi, Ensemble3 center of excellence

Poster presentation-12

Melt grown black Titanium Oxide: Novel optoelectronic material

Kingshuk Bandopadhyay, ENSEMBLE3 Centre of Excellence, Wolczynska 133, 01-919 Warsaw, Poland

Poster presentation-13

Synthesis and characterization of NbSe₂ crystals and nanofilms

Dimitre Dimitrov, Institute of Solid State Physics-Bulgarian Academy of Sciences | Institute of Optical Materials and Technologies, Bulgarian Academy of Sciences | Consiglio Nazionale delle Ricerche, Istituto per la Microelettronica e Microsistemi

Poster presentation-14

Salts of amino acids with a dimeric cation of the [A(1)+...A(2)] type with polar symmetry

Aram Petrosyan, Institute of Applied Problems of Physics

Poster presentation-15

Crystal growth and optical properties of functional Tb³⁺-doped orthoborates Alexander Kokh, Institute of geology and mineralogy, Russia

Poster presentation-16

Microscopic ordering of supercooled water on the ice basal face

Kenji Mochizuki, Department of Chemistry, Zhejiang University, China

Poster presentation-17

Effect of solution environment on the growth of DNA-functionalized nanoparticle crystals

Shoko Kojima, Nagoya University, Japan | Japan Synchrotron Radiation Research Institute (JASRI) | Institute of Materials and Systems for Sustainability, Japan, et al.

Poster presentation-18

Novel experimental data on hydrothermal growth of phenakite single crystals with Si-Ge substitution

Valentin Kovalev, Lomonosov Moscow State University | DS Korzhinskii Institute of Experimental Mineralogy of the Russian Academy of Sciences, et al.

Poster presentation-19

Crystal growth and high pressure Raman spectroscopy study of germanium-rich quartz-like solid solution

Valentin Kovalev, Lomonosov Moscow State University | DS Korzhinskii Institute of Experimental Mineralogy of the Russian Academy of Sciences, et al.

Poster presentation-20

Synthesis of Large Norsethite Crystals in Aqueous Ammonium Nitrate Solutions

Harutoshi Asakawa, Graduate School of Sciences and Technology for Innovation Yamaguchi University, et al.

Poster presentation-21

Atomistic Dynamics of "Floating Island" Transiently Formed in Two-Dimensional Nucleation

Masaya Sakakibara, Department of Chemistry, The University of Tokyo, et al.

Poster presentation-22

Investigation of metal-induced crystallization mechanism on amorphous SiO2 Dario Florio, Università di Parma

Poster presentation-23

Fast Crystal Growth: analysis of field and atomistic data of simulation Peter Galenko, Friedrich Schiller University Jena, Germany

Poster presentation-24

Microstructure and properties of crystals growing from undercooled Ni-based superalloys

Peter Galenko, Friedrich Schiller University Jena

Poster presentation-25

Atomic-scale mechanisms on the stepwise growth of $Mo_xW_{1-x}S_2$ into hexagonal flakes

Jiawei Huang, Nanchang University

Poster presentation-26

An atomic-scale study on deoxidation process of MoO_3 via in situ transmission electron microscopy.

Jiaqi Chen, Nanchang University

Poster presentation-27

Investigation of the optoelectronic properties of hybrid heterojunction Roman Yatskiv, Institute of Photonics and Electronics of the Czech Academy of Sciences, Czech Republic

Poster presentation-28

Growth dynamics and modelling of organic semiconductor thin films subject to post-growth processes

Alice Pancaldi, Department of Materials Science, University of Milano-Bicocca

Poster presentation-29

Growth of high-density InGaAs/AllnGaAs quantum dots by MOVPE targeting the 1.3-micron window

Swati Mukherjee, Tyndall National Institute/ University College Cork

Poster presentation-30

Different strategies for GaN-MoS2 and GaN-WS2 core—shell nanowire growth Kevon Kadiwala, Institute of Solid State Physics, University of Latvia

Poster presentation-31

Chemical bath deposition of nanostructures in continuous-flow reactors Ondřej Černohorský, Institute of Photonics and Electronics, Prague, Czech Academy of Sciences

Poster presentation-32

Growing Ga and In oxide hydroxide nanocrystals on GaAs and InAs crystalline substrates by hot water immersion

Zahra Jahanshah Rad, University of Turku

Poster presentation-33

Growth of GalnN/GalnN MQWs on nanocolumns with thick GalnN buffer layer using RF-MBE

Hiromi Akagawa, Kogakuin University

Poster presentation-34

Dopants impact on planar GaAs nanowires growth

Nikolai Sibirev, The Faculty of Physics, Saint-Petersburg State University

Poster presentation-35

Nanowire ZnO/GaN heterostructures prepared by chemical bath deposition Jan Grym, Institute of Photonics and Electronics of the CAS

Poster presentation-36

Investigating the structural, and Magnetic Properties of Fe3Se4 nanoparticles Dimple Shah, Sardar Vallabhbhai National Institute of Technology, Surat, India

Poster presentation-37

Effect of Mo doped in Vanadium Pentoxide (V₂O₅) for dye degradation Dimple Shah, Sardar Vallabhabhai National Institute of Technology, Surat, Gujarat

Poster presentation-38

Single-crystal growth of multicomponent silicon clathrate compounds by using sodium-tin fluxes

Haruhiko Morito, Institute for Materials Research, Tohoku University | Institute of Multidisciplinary Research for Advanced Materials, Tohoku University

Poster presentation-39

Local droplet etching holes in vicinal InGaAs/GaAs(111)A

Artur Tuktamyshev, University of Milano Bicocca

Poster presentation-40

Improvement of SiC single crystal by a novel method

Jun Fu, Meishan Tianle semiconductor materials Co., Ltd.

Poster presentation-41

Study on future prospects for feasibility of novel modifications in melt technique to improve properties of crystals for the development of Reference Materials for Thermoelectric Applications

ANUJ KRISHNA, CSIR-NATIONAL PHYSICAL LABORATORY

Poster presentation-42

Growth and polarized spectral properties of Tm:Ca₃TaGa₃Si₂O₁₄ crystal for mid-infrared laser

Pingzhang Yu, Shandong University

Poster presentation-43

Hydride Vapor Phase Epitaxial Growth of ZnSe on GaAs Substrates and Orientation-Patterned GaAs Templates for Nonlinear Optical Applications Shivashankar Vangala, Air Force Research Laboratory Wright-Patterson AFB, OH 45433, USA

Poster presentation-44

Optical and laser properties of YAG:Nd crystals grown by the HDC method in carbon-containing atmosphere

Igor Pritula, Institute for Single Crystals of NAS of Ukraine

Poster presentation-45

Investigation of defect structure and domains in Ca $_9$ La (VO $_4$) $_7$ and Ca $_{10}$ Li (VO $_4$) $_7$ single crystals grown by the Czochralski method

Igor Pritula, Institute for Single Crystals, NAS of Ukraine

Poster presentation-46

Crystal growth and photorefraction of uranium-doped lithium niobate series crystals

Tian Tian, Shanghai Institute of Technology | Nankai University

Poster presentation-47

Ultraviolet laser-induced damage characteristics of 70% deuterated potassium dihydrogen phosphate crystals

Baoan Liu, State Key Laboratory of Crystal Materials, Shandong University, Jinan 250100, China | Laboratory of Thin Film Optics, Shanghai Institute of Optics and Fine Mechanics, Shanghai 201800, China. | Research Center of Laser Fusion, China Academy of Engineering Physics, Mianyang 621900, China

Poster presentation-48

Concentration distribution of Pb2+ ions in PbF2:BaF2 crystals

Gabriel Buse, West University of Timisoara - ICAM

Poster presentation-49

Czochralski-grown LGSB crystals as high-performance NIR laser crystals and SFD crystals in the VIS spectral range

Lucian Gheorghe, National Institute for Laser, Plasma and Radiation Physics

Poster presentation-50

Approach for AIN White-light luminescence by adjusting the bivalence and trivalence of Eu doped ratio

YINGDA QIAN, Department of Physics, Tokyo University of Science, Kagurazaka, Tokyo, Japan

Poster presentation-51

Crystal growth, morphology, and luminescence properties of selected multicomponent garnet single crystals for laser applications
Jan Pejchal, Institute of Physics, Czech Academy of Sciences

Poster presentation-52

The effect of TiO₂ crystalline form on microstructure and optical features of Zn₂TiO₄ doped with Mn

Tetyana Kryshtab, Instituto Politécnico Nacional

Poster presentation-53

A new family of NLO crystals MSr3Be3B3O9F4 (M=Na, Sr) for 266nm generation: crystal growth and optical properties

Lijuan Liu, Technical Institute of Physics and Chemistry, Chinese Academy of Science

Poster presentation-54

Investigation on Ce doped Lu(Y) 3Al5O12 single crystal fi bers grown by laser heated pedestal growth method

Anhua Wu, Key Laboratory of Transparent Optical Functional Inorganic Materials, Shanghai Institute of Ceramics, Chinese Academy of Sciences, Shanghai 201899, China | Center of Materials Science and Optoelectronics Engineering, University of Chinese Academy of Sciences, Beijing 100049, China

Poster presentation-55

Growth of (Lu_{1-x}Tb_x)₂O₃ single crystals by the Optical Floating Zone Oleg Sidletskiy, Ensemble3 Centre of Excellence, et al.

Poster presentation-56

First-principles calculation of phonon properties of KDP crystal Guokai Hao, Shandong University

Poster presentation-57

Lithium Niobate Single Crystal: revisiting the properties for application in Galileo Solar Space Telescope

Franciele Carlesso, National Institute for Space Research (INPE) | Federal University of São Paulo

Poster presentation-58

Optical properties of pure and Sn-doped β -Ga2O3 single crystals grown by optical Float Zone technique

Joseph Daniel Devasirvatham, Kyungpook National University

Poster presentation-59

High-power ultraviolet laser generation at 355 nm and 266 nm using sumfrequency method based on La₂CaB₁₀O₁₉ crystal

Lirong Wang, Technical Institute of Physics and Chemistry, Chinese Academy of Sciences

Poster presentation-60

Formation of secondary phase particles in compound semiconductor bulk crystals grown from melt

Yadong Xu, Northwestern Polytechnical University, et al.

Poster presentation-61

Hybrid density functional theory calculations for the electronic and optical properties of Fe³⁺- doped KDP crystals

Mingxia Xu, State Key Laboratory of Crystal Materials, Shandong University | Department of Physics, School of Mathematics and Physics, University of Science and Technology Beijing

Poster presentation-62

Theoretical study for structural stability and electronic properties induced by various point defect of KDP and ADP crystals

Tingting Sui, Department of Physics, School of Mathematics and Physics, University of Science and Technology Beijing, Beijing 100083, China

Poster presentation-63

Approach of enhancing the crystal perfection in subsurface layer of *epi-ready* (-2 01) β - Ga $_2$ O $_3$ substrates

Pavel Butenko, loffe Institute

Poster presentation-64

A study on the architecture of defects in co-doped ceria electrolytes using synchrotron light

Sara Massardo, University of Genoa, et al.

Poster presentation-65

Manifestation of the Kirkendall effect in the process of thermal decomposition of In_xGa_{1-x}N/GaN MQWs – first principles studies

Roman Hrytsak, Institute of High Pressure Physics "Unipress", PAS

Poster presentation-66

Effect of noble gas defect on the acceptor formation in ZnO

LOVELESH LOVELESH, Centre of Excellence ENSEMBLE3 Sp. z o. o., Wolczynska Str. 133, 01-919, Warsaw, Poland

Poster presentation-67

New insights into design of the metamorphic buffer layers

Mikhail Chernov, loffe Institute

Poster presentation-68

Crystal growth of lattice-relaxed high-quality AlGaN templates and fabrication of UV-B laser diodes on these templates

Motoaki Iwaya, Meijo University, et al.

Poster presentation-69

Growth and characterization of gallium phosphide on gallium oxide substrate for heterojunction diodes

Sebastian Lourdudoss, KTH - Royal Institute of Technology

Poster presentation-70

MBE growth of SnTe films on GaAs substrates with ZnTe buffer layers Masakazu Kobayashi, Waseda University

Poster presentation-71

The development of mid-infrared and far-infrared nonlinear ZGP crystals Chunhui Yang, Harbin Institute of Technology

TUE, 1 AUG - POSTER SESSION 02

16:30 - 18:30

Poster presentation-01

Growth of detector-grade CdTe crystal by the Vertical Gradient Freeze method with a Cd reservoir

Tao Wang, Northwestern Polytechnical University | Imdetek Corp. Ltd.

Poster presentation-02

Reduction of heater power and oxygen content in Si crystals by modification of continuous Czochralski furnace

Jyh-Chen Chen, National Central University

Poster presentation-03

The introduction of an experimental apparatus used for growing large size of crystals from low temperature solution in space

Youting Song, Institute of Physics, Chinese Academy of Sciences

Poster presentation-04

3D analysis of dislocation density in a Ga₂O₃ crystal grown by a vertical Bridgman method

KOICHI KAKIMOTO, NICHe, Tohoku Univ. | C&A Co. | Japan Fine Ceramics Center RIAM, Kyushu Univ. IMR, Tohoku Univ.

Poster presentation-05

The potential of the hen eggshell as rare earth element sorbent and segregator Remi Rateau, Trinity College Dublin, the University of Dublin

Poster presentation-06

The effect of rare earth elements in the crystallisation of calcium carbonate from solution at ambient temperature

Luca Terribili, Trinity College Dublin

Poster presentation-07

-101 gypsum contact twins experimentally obtained from a calcium carbonate rich solutions: mineralogical implications for natural gypsum deposits ANDREA COTELLUCCI, UNIVERSITY OF TURIN

Poster presentation-08

Study on the Growth of Large-size Sapphire Plate by EFG Method Peng Zhao, Research Institute of Synthetic Crystals, et al.

Poster presentation-09

Bridgman growth of high - purity crystals for rare events physics

Yong Zhu, Shanghai Institute of Ceramics, Chinese Academy of Sciences | Gran Sasso Science Institute

Poster presentation-10

Dislocation generation during Czochralski silicon growth

Rania Hendawi, Norwegian University of science and technology, et al.

Poster presentation-11

Growth of 2 inch diameter Lil:Eu in carbon coated crucible and effect of post growth thermal treatment on scintillation light yield.

Durgesh Singh Sisodiya, Homi Bhabha National Institute, Mumbai

Poster presentation-12

Improvement of crystalline quality by using BN cap in solution growth of SiC single crystal

Peng Gu, Meishan Boya Advanced Materials Co., Ltd. | School of Earth and Space Sciences, Peking University

Poster presentation-13

Effect of macrostep height on formation of solvent inclusion in SiC solution growth

Yuma Fukami, Nagoya University, et al.

Poster presentation-14

AC poling of PMN-PT single crystals used for medical ultrasonic transducers Haosu Luo, Shanghai Institute of Ceramics, Chinese Academy of Sciences, China

Poster presentation-15

Numerical Modeling on spiral formation of Cz-β-Ga2O3 crystal growth considering solidification kinetic effect

Masaya Iizuka, STR Japan K.K., et al.

Poster presentation-16

Crystal growth and characterization of organic single crystal 2-amino 4-methyl pyridinium oxalate : $(C_7H_9N_2O_2)$

Joseph Daniel Devasirvatham, The Center for high-energy Physics, Kyungpook National University, Daegu 41566, South Korea

Poster presentation-17

Growth of pure and doped Bi₄Si₃O₁₂ single crystals for optical applications Jiayue Xu, Shanghai Institute of Technology

Poster presentation-18

Optimization of thermal field for 8-inch 4H-SiC single crystal grown by PVT method

Jun Fu, Meishan Tianle semiconductor materials Co., Ltd.

Poster presentation-19

Coupled thermal-solidification process simulation of sapphire growth

Raluca Trasca, Materials Center Leoben, Roseggerstr.12, 8700 Leoben, Austria

Poster presentation-20

Investigating the various effects of boron doping during the growth of Czochralski germanium ingots

Aravind Subramanian, Leibniz institute for crystal growth

Poster presentation-21

The tendency of crystallization of bioactive borate glasses

Tina Tasheva, Department of Silicate Technology, University of Chemical Technology and Metallurgy, 8, Kl. Ohridski Blvd., Sofia 1756, Bulgaria

Poster presentation-22

Growth and characterization of Pr-doped Ca₂RuO₄ single crystals Mariateresa Lettieri. CNR-SPIN

Poster presentation-23

Study of gallium nitride solubility in ammonothermal alkaline solution under various physicochemical conditions

Karolina Grabianska, Institute of High Pressure Physics Polish Academy of Sciences

Poster presentation-24

Growth and composition control of Tb₃Ga₅O₁₂ crystals

Miki Watanabe, OXIDE corporation | University of Yamanashi, et al.

Poster presentation-25

Study on growth and doping of large scale gallium selenide crystals

Chonggiang Zhu, Harbin Institute of Technology

Poster presentation-26

PdSe2 Single Crystals Synthesized by Flux Method

Vera Marinova, Institute of Optical Materials and Technologies, Bulgarian Academy of Sciences, Sofia, Bulgaria

Poster presentation-27

Experimental investigation of shape control criteria for wire fabrication of alloys by the dewetting micro-pulling-down method

Rikito Murakami, Tohoku University | C&A Corporation, Japan

Poster presentation-28

Concurrent crystallization of two active pharmaceutical ingredients using polymers

Jonghwi Lee, Chung-Ang University

Poster presentation-29

LaBr₃:Ce -⁶LiBr composite crystal for dual gamma-neutron detection application, crystal growth and characterization

Vladimir OUSPENSKI, Luxium Solutions | Saint-Gobain Research Paris

Poster presentation-30

Rare-earths doped Y₂O₃ laser materials

George Stanciu, National Institute for Laser, Plasma and Radiation Physics, Laboratory of Solid-State Quantum Electronics, Magurele 077125, Romania

Poster presentation-31

Enhancement of catalytic activity of MOF-74 by providing extra open metal sites for cyanosilylation of aldehydes

Sojin Oh, Yonsei University

Poster presentation-32

Compromising conflicted spatial-arrangements of two mixed linkers in metalorganic frameworks

Gihyun Lee, Yonsei University

Poster presentation-33

Surface charge-directed selective and outstanding catalytic activities of porous M@UiO-66 composites (M = Pt or Ag) for reduction of organic pollutants

Sujeong Lee, Yonsei University

Poster presentation-34

Hybrid nanofillers loaded epoxy resin; Synthesis, characterizations and dielectric spectroscopy

DIMPLE SHAH, Sardar Vallabhbhai National Institute of Technology, Surat

Poster presentation-35

Improved dissolution rates of naproxen and its cocrystals via eutectic formation

IL WON KIM, Soongsil University

Poster presentation-36

Predicting Particle Properties of Organic Materials using Surface Descriptors Alexandru Moldovan, Cambridge Crystallographic Data Centre

Poster presentation-37

Impact of the efavirenz polymorphism on the mechanical properties and dissolution assays

Ana Maria Santo, Post-Graduation Program on Engeeniring and Science Materials - PPGECM Institute of Science and Technology - ICT Federal University of Sao Paulo - UNIFESP | Micro and nanostructures Laboratory - LMNano Institute of Technology on Phamaceuticals - ITF Farmanguinhos (FIOCRUZ)

Poster presentation-38

Eutectic mixtures containing ezetimibe (ingredient pharmaceutical active): phase diagrams, solid state characterization and dissolution essays

Ana Maria Santo, Post Graduate on Engineering and Science Materials Program - PPGECM Institute of Science and Technology - ICT Federal University of São Paulo - UNIFESP

Poster presentation-39

Probing Nonlinear Optical (NLO) Microspectroscopy for Heterogeneous Crystallization Development

Basanta Saikia, KU Leuven Kulak

Poster presentation-40

Crystallization of poly (L-lactide) / Flax Fiber biocomposites: influence of the matrix Molecular weight

SEVERINE A.E. BOYER, MINES Paris PSL CEMEF CNRS 7635 1, Rue Claude Daunesse 06904 SOPHIA ANTIPOLIS, FRANCE

Poster presentation-41

2D Calculation of Propagating Thermal Waves surrounding DendritesSEVERINE A.E. BOYER, MINES Paris PSL CEMEF CNRS 7635 1, Rue Claude Daunesse 06904 SOPHIA ANTIPOLIS, FRANCE

Crystallization on the eggshell membrane: calcium phosphate nucleation on a calcium carbonate nucleating membrane

Jaime Gómez-Morales, Laboratorio de Estudios Cristalográficos Instituto Andaluz de Ciencias de la Tierra Consejo Superior de Investigaciones Científicas-University of Granada

Poster presentation-43

Magnesium, manganese and cobalt substituted nanocrystalline apatites obtained by hydrothermal transformation of biogenic calcium carbonate.

Sandra María Cano Plá, Laboratorio de Estudios Cristalográficos. Instituto Andaluz de Ciencias de la Tierra. Consejo Superior de Investigaciones Científicas / Universidad de Granada. Avda. de Las Palmeras, nº 4. E-18100, Spain

Poster presentation-44

Europium and Terbium doped apatite obtained by hydrothermal transformation of biogenic calcium carbonate from oyster shells.

Sandra María Cano Plá, Laboratorio de Estudios Cristalográficos. Instituto Andaluz de Ciencias de la Tierra. Consejo Superior de Investigaciones Científicas/ Universidad de Granada. Avda. de Las Palmeras, nº 4 E-18100, Spain.

Poster presentation-45

Crystallization conditions, morphology and crystal structures of cyclic peptoids

Giovanni Pierri, University of Salerno

Poster presentation-46

Chitosan/oxidized chitin composite films with potential applications in food packaging

Angelica Mucaria, Dipartimento di Chimica "Giacomo Ciamician", Alma Mater Studiorum – Università di Bologna, via F. Selmi 2, 40126 Bologna, Italy

Poster presentation-47

Growth and characterization of InP templates for Zn₂P₃ AbsorbersDidem Dede, École Polytechnique Fédérale de Lausanne (EPFL)

Poster presentation-48

Mechanochemistry for photovoltaics and green energy

Elena Del Canale, IMEM-CNR | Università degli Studi di Parma, et al.

Poster presentation-49

Metal halide perovskite single crystals for highly stable and efficient photovoltaic devices

Sang Hyuk Im, Korea University, et al.

Poster presentation-50

Enhancing intermediate band solar cells performances through quantum engineering of dot states by Droplet Epitaxy

Stefano Sanguinetti, University of Milan-Bicocca

Poster presentation-51

Spectroscopic properties of Bi₃TeBO₉ ceramics doped with rare earth ions Dobroslawa Kasprowicz, Faculty of Materials Engineering and Technical Physics, Poznan University of Technology, Poznan, Poland

Detailed model of diamond crystal growth by MPCVD

Andrey Smirnov, Semiconductor Technology Research d.o.o. Beograd

Poster presentation-53

Cs2AgBiBr6 Lead-Free Perovskite for Solar cells and indoor-outdoor **Applications**

Paola Prete. IMM-CNR

Poster presentation-54

MOVPE-grown pseudomorphic GaAsP/(100)GaAs heterostructures for fabrication of 1.7 eV top junction in 4-terminal tandem III-V/Si solar cells Paola Prete, IMM-CNR, et al.

Poster presentation-55

Optimizing the Performance of (Sb_{0.2}Sn_{0.8})_{0.5}(S_{0.9}Se_{0.1})_{0.5} Crystal-Based Self-**Powered Photodetectors**

Dimple Shah, Sardar Vallabhbhai National institute of Technology, Surat | Sardar Vallabhbhai National institute of Technology, Surat | Sardar Vallabhbhai National institute of Technology, Surat

Poster presentation-56

Crystallization processes for photovoltaic silicon ingots and their effect on solar cell performance

Marisa Di Sabatino, Norwegian University of Science and Technology (NTNU)

Poster presentation-57

Growth and characterization of halogenobismuthates of amino acids Aram Petrosyan, Institute of Applied Problems of Physics

Poster presentation-58

Polyiodides of amino acids

Aram Petrosyan, Institute of Applied Problems of Physics

Poster presentation-59

Thermodynamic and kinetic modulation of methylammonium lead bromide crystallization revealed by in situ monitoring

Amnon Ortoll-Bloch, Bowdoin College, Department of Chemistry

Poster presentation-60

Numerical studies on the dislocation density in the n-type 4H-SiC

Xuefeng Han, State Key Laboratory of Silicon Materials & School of Materials Science and Engineering, Zhejiang University, China | Institute of Advanced Semiconductors & Zhejiang Provincial Key Laboratory of Power Semiconductor Materials and Devices, Hangzhou Global Scientific and Technological Innovation Center, Zhejiang University, China | Ultra-precision Machining Research Center, Zhejiang University of Technology, China, et al.

Poster presentation-61

Numerical analysis of cryogenic preparation of methane and hydrogen Xuefeng Han, Hangzhou Global Scientific and Technological Innovation Center, Zhejiang University, China | Univ. Grenoble Alpes, CNRS, Grenoble INP, SIMaP, F-38000 Grenoble, France | INAC-SBT, Grenoble, France

Growth of mc-Silicon ingot by DS Process: Computational Modeling and Experimental validation

Srinivasan Manikam, SSN College of Engineering

Poster presentation-63

Numerical study of thermal stresses and dislocation dynamics during growth of oxide and fluoride crystals from melt

Andrejs Sabanskis, Institute of Numerical Modelling, University of Latvia, et al.

Poster presentation-64

Numerical investigation of the effect of the temperature on surface supersaturation in the rapid growth of KDP crystals

Jianyu Bai, sunxun@sdu.edu.cn

Poster presentation-65

Effect of unsteady melt flow features on the melt/crystal interface shape and thermal stresses in Cz Ga₂O₃ crystal growth

Vladimir Artemyev, STR Belgrade

Poster presentation-66

Numerical modelling of feed rod melting dynamics during floating zone silicon crystal growth

Maksims Surovovs, University of Latvia

Poster presentation-67

Determining the Complete Thermodynamics of Calcite Kink Sites for Crystal Growth and Dissolution

Blake Armstrong, Curtin University

Poster presentation-68

Crystal Shape and Topography: Prediction and Optimisation with the CrystalGrower Model

Alvin Walisinghe, Curtin University

Poster presentation-69

Serially diluting centrifugal microfluidics for high-throughput synthesis of various shape of gold nanoparticles

TAE SEOK SEO, Kyung Hee University

Poster presentation-70

Solution volume effects on spontaneous chiral symmetry breaking of sodium chlorate crystals

Bum Jun Park, Kyung Hee University, et al.

Poster presentation-71

InGaN multiple-quantum-well light-emitting diodes grown with an underlying superlattice for light detection

Chia-Lung Tsai, Chang Gung University

Poster presentation-72

Bi-chalcogenides films grown by physical vapor deposition technique Anita Guarino, CNR-SPIN Salerno

MoS₂-gCN/RGO Ternary Composite for Electrochemical Detection of Serotonin Wan-Chin Yu, Institute of Organic and Polymeric Materials, National Taipei University of Technology, Taipei 106, Taiwan., et al.

Poster presentation-74

Crystal growth, optical and scintillation properties of (La,Gd)₂Si₂O₇:Tb crystals Oleg Sidletskiy, Institute for scintillation materials NAS of Ukraine

Poster presentation-75

Enhancement in optical, mechanical, thermal and electrical properties of organic crystals by selective dye doping

Binay Kumar, University of Delhi | University of Delhi | University of Delhi

16:30 - 18:30

Poster presentation-01

Study of parameters for CVD growth of 2-dimensional MoS₂ by liquid phase molybdenum precursors

Fiorenza Esposito, University of Parma | IMEM-CNR

Poster presentation-02

Concurrent Magnesium and Hydrogen Intercalation in Epitaxial Graphene Patrick Rondomanski, Pennsylvania State University

Poster presentation-03

Growth and Characterization of 2D superconductor NdO _{0.5} F _{0.5} BiS ₂ Changsheng Chen, University of Zurich | Fudan University

Poster presentation-04

Physical vapour deposition of atomically-thin crystals of the helimagentic material NiBr₂

Ivona Košić, University of Valencia, The Institute of Molecular Science (ICMol)

Poster presentation-05

Ambient pressure chemical vapor deposition of Tellurium based 2D layers Alessio Lamperti, CNR-IMM Unit of Agrate Brianza

Poster presentation-06

New Al-based microcrystalline Metal-Organic Nanosheets (MONs) as efficient fluorescent sensor for Fe(III) in water

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Chieh Hu, 1. Department of Mechanical Engineering, National Central University, Taoyuan City, Taiwan 2. Research and Development Division, Global Wafer Co., Ltd, Hsinchu City, Taiwan

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